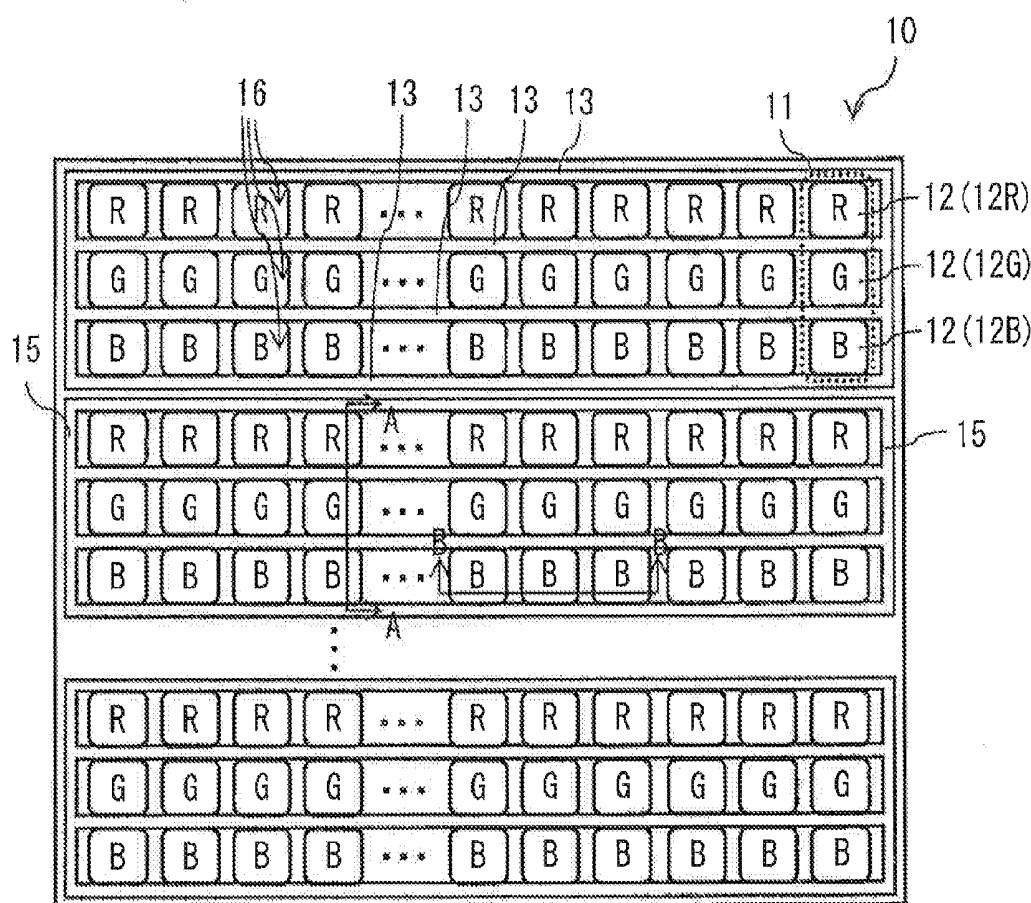




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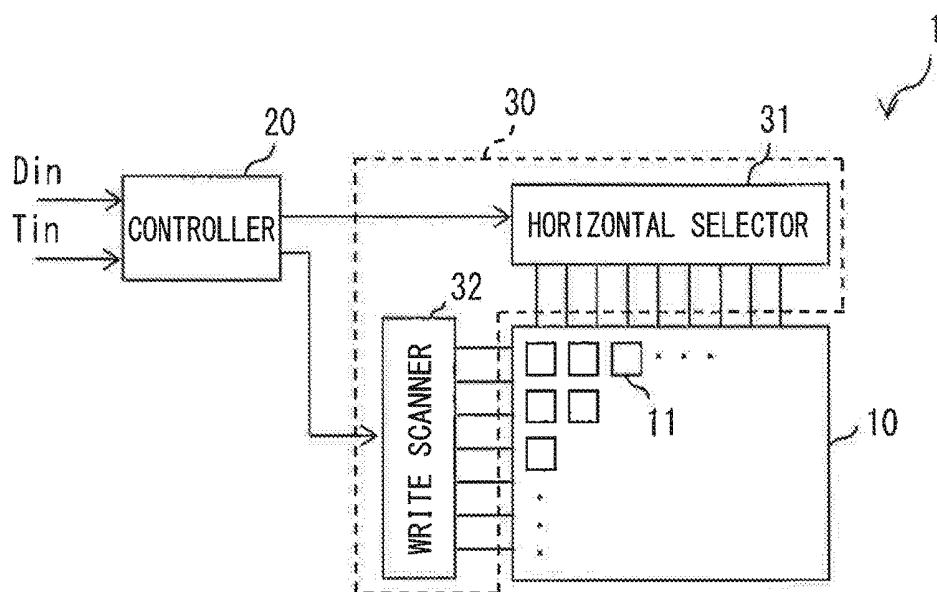


FIG. 1

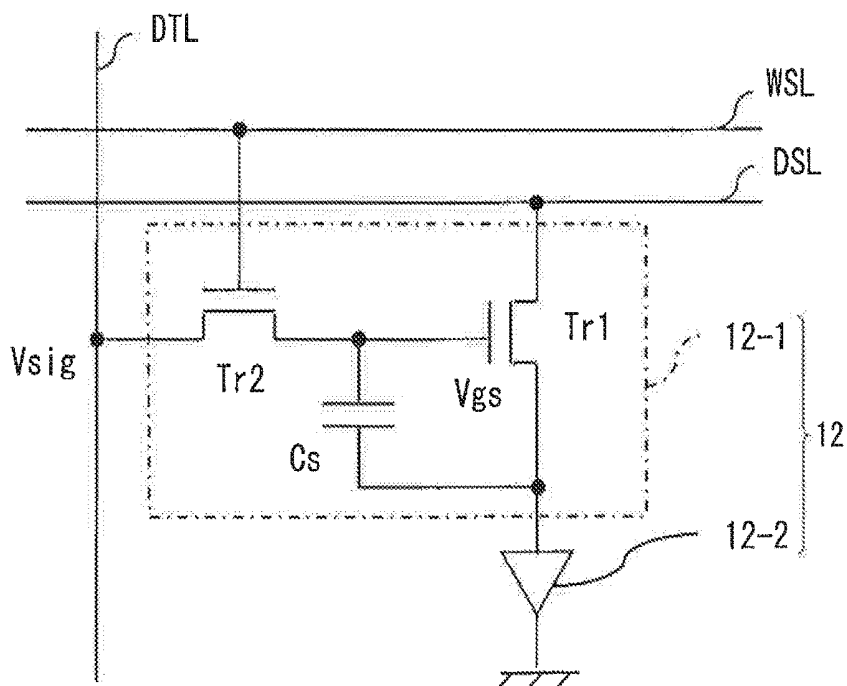


FIG. 2

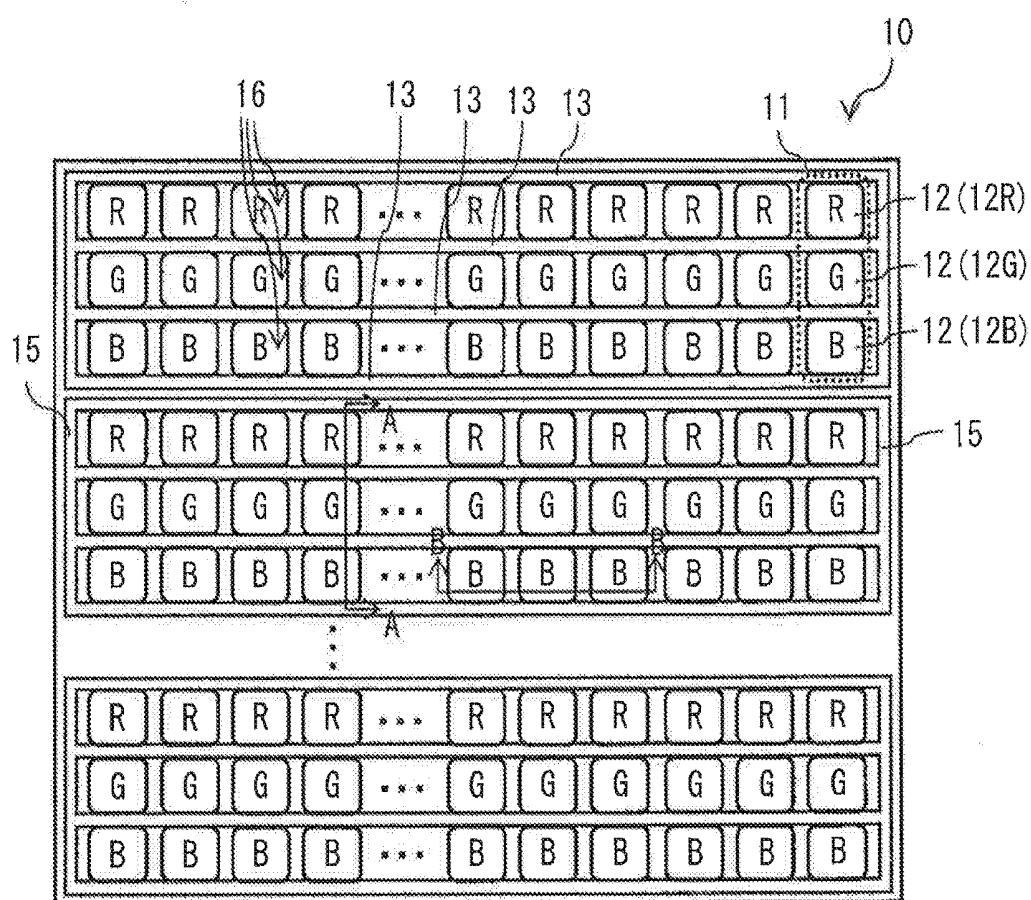


FIG. 3

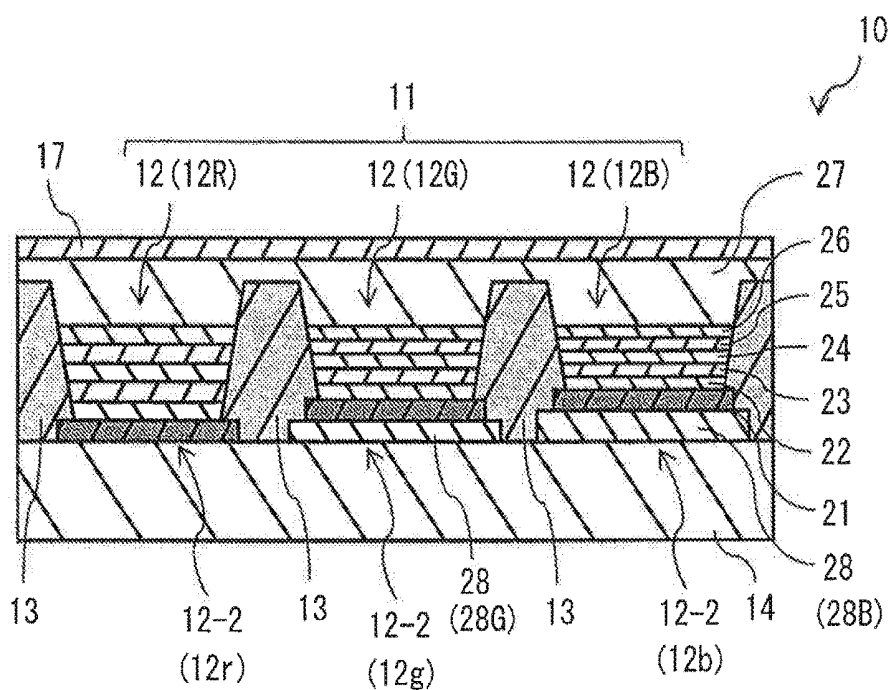


FIG. 4

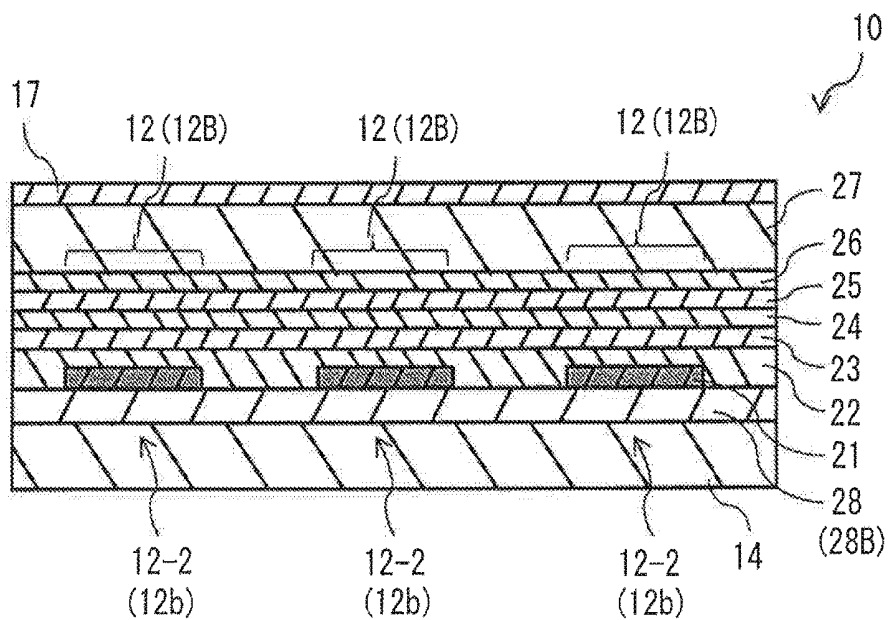
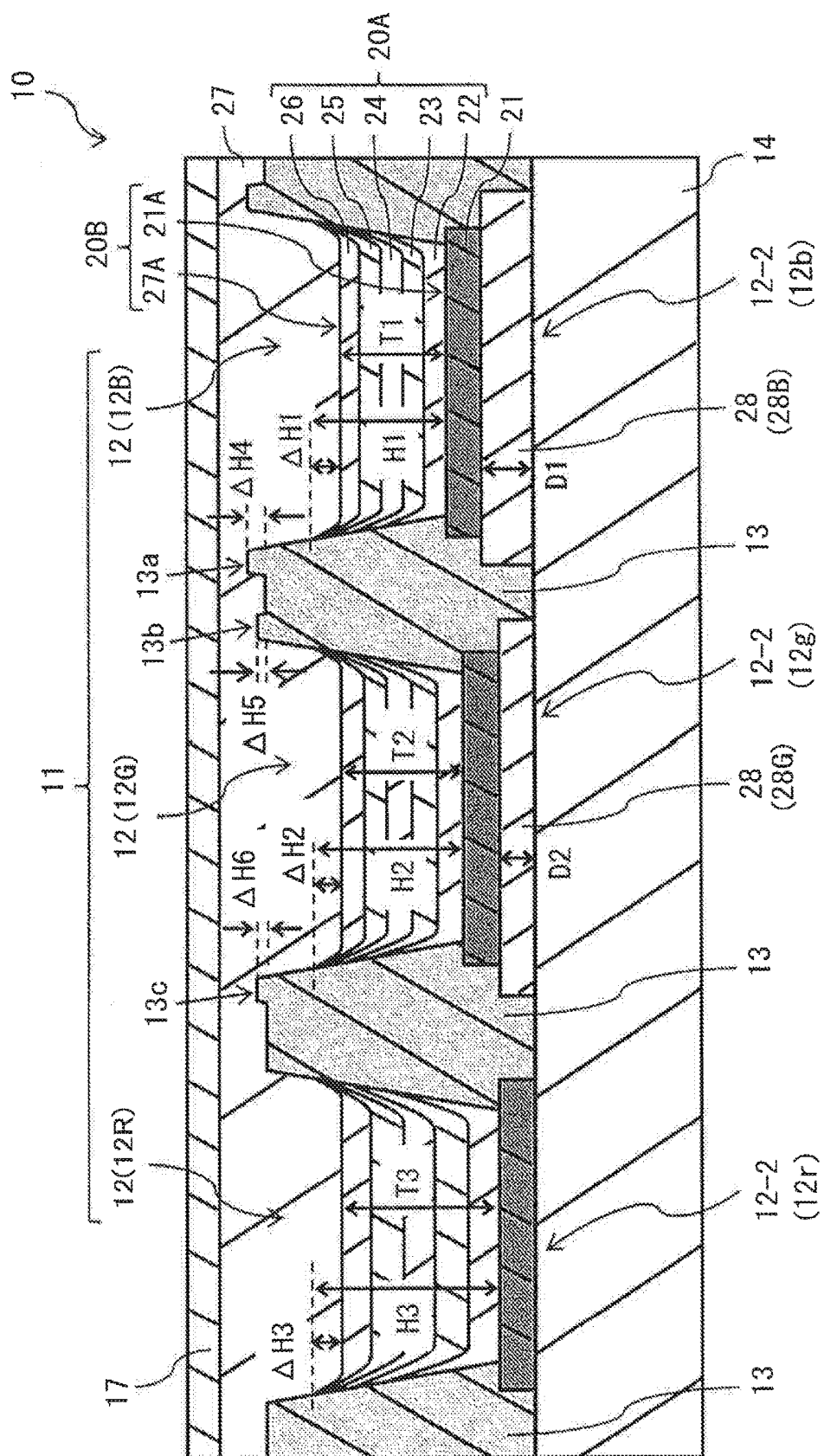
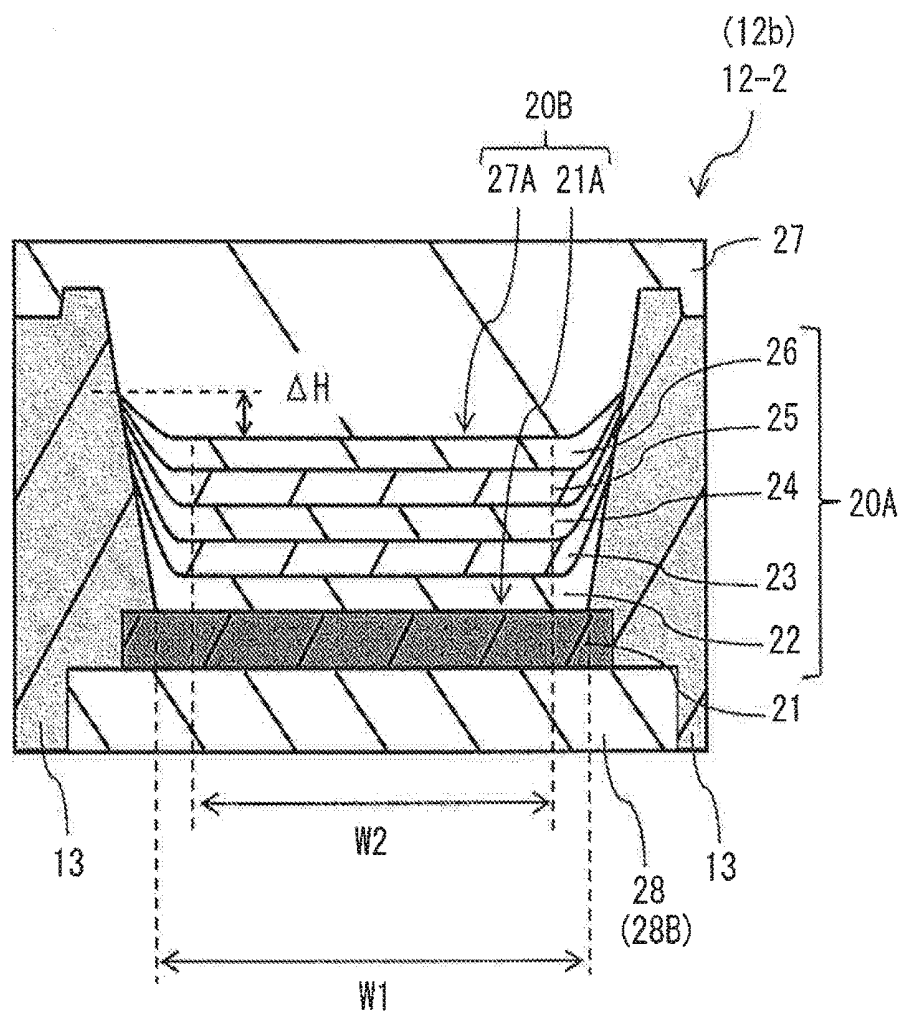


FIG. 5



6514



$$\text{FLAT RATE } R = \frac{W2}{W1} \times 100 \quad [\%]$$

FIG. 7

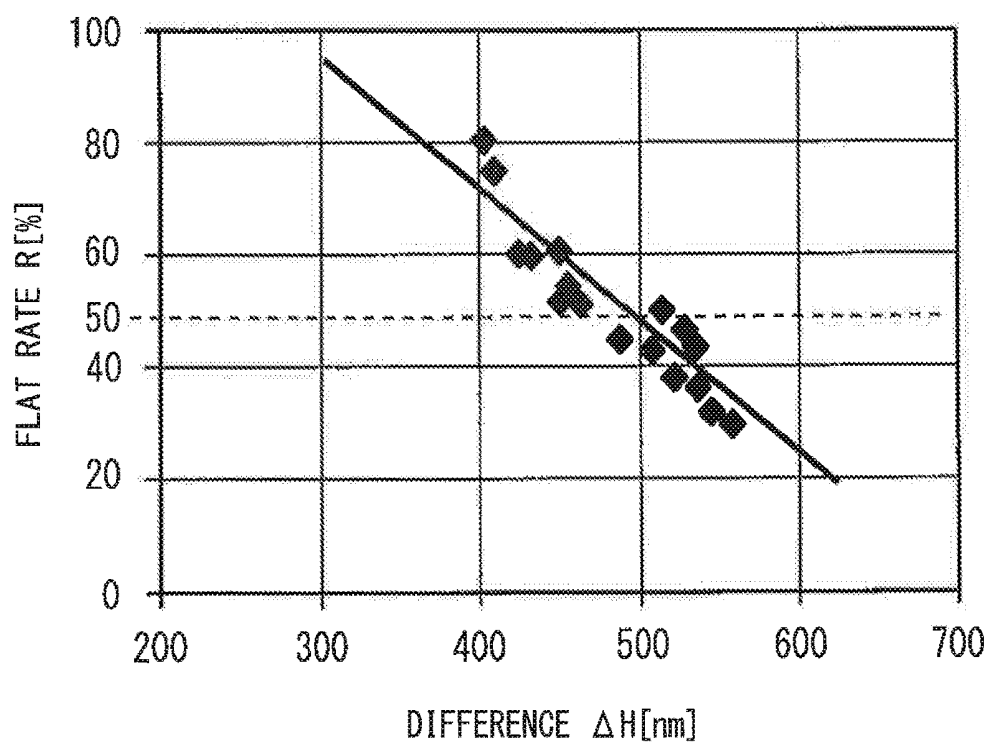


FIG. 8

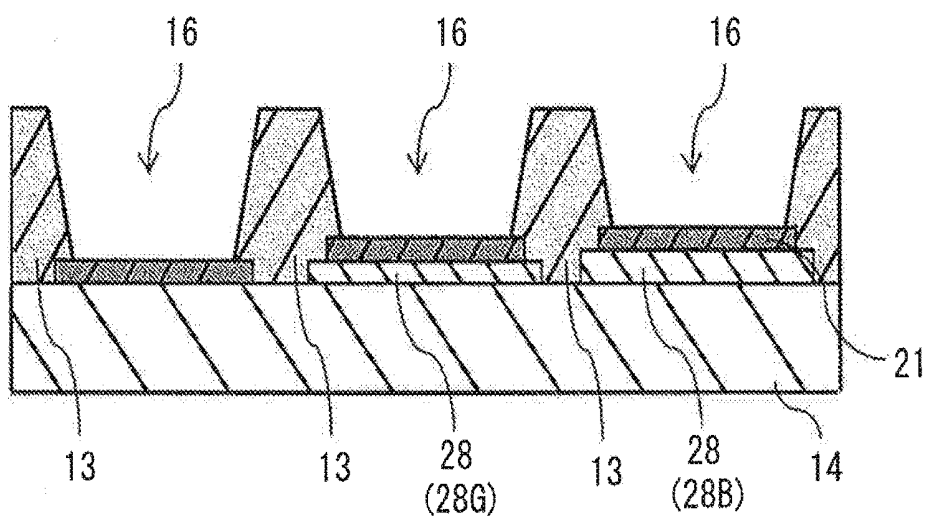


FIG. 9A

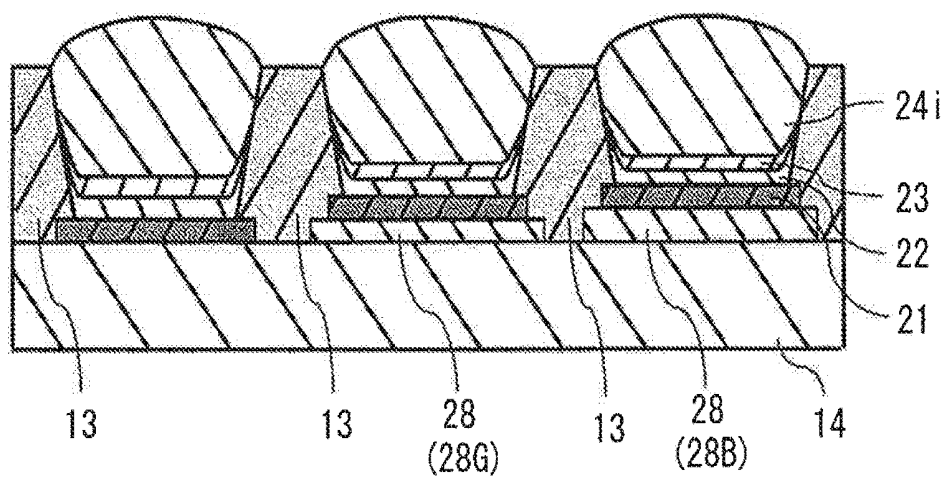


FIG. 9B

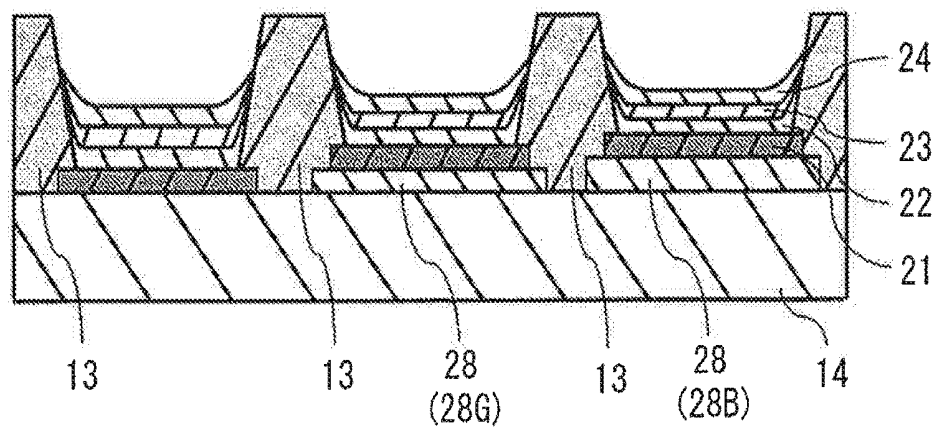


FIG. 9C

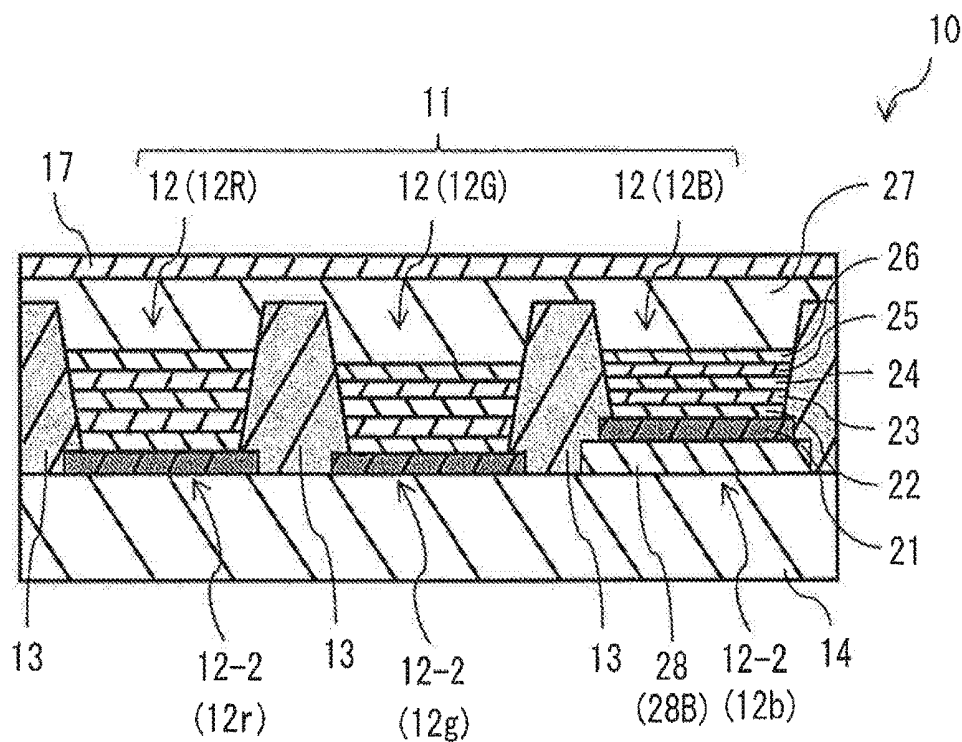


FIG. 10

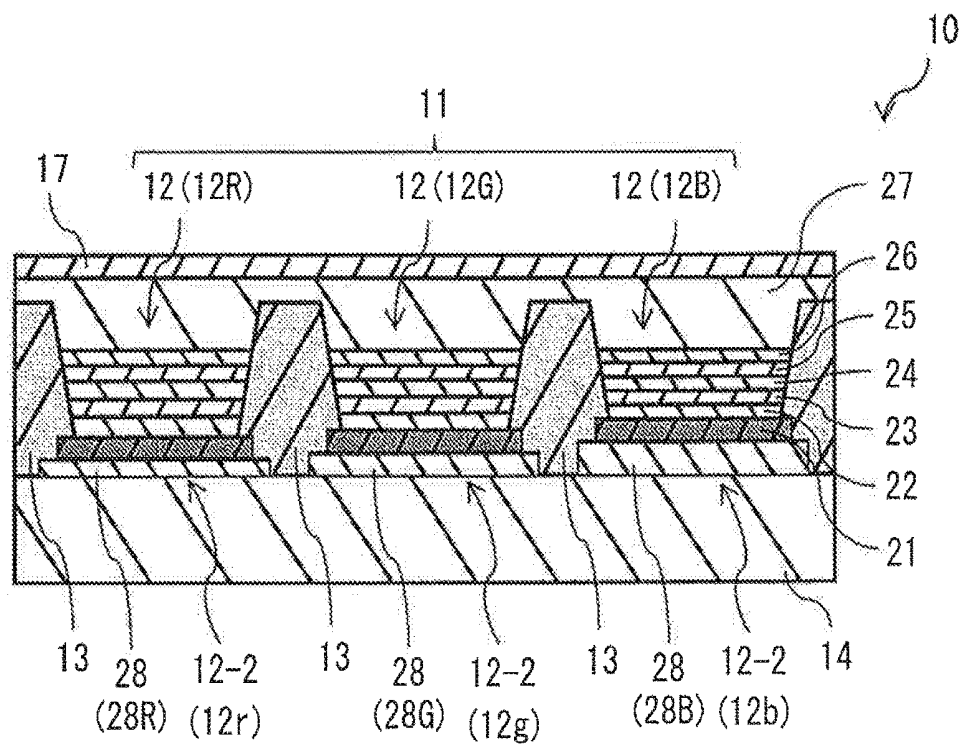
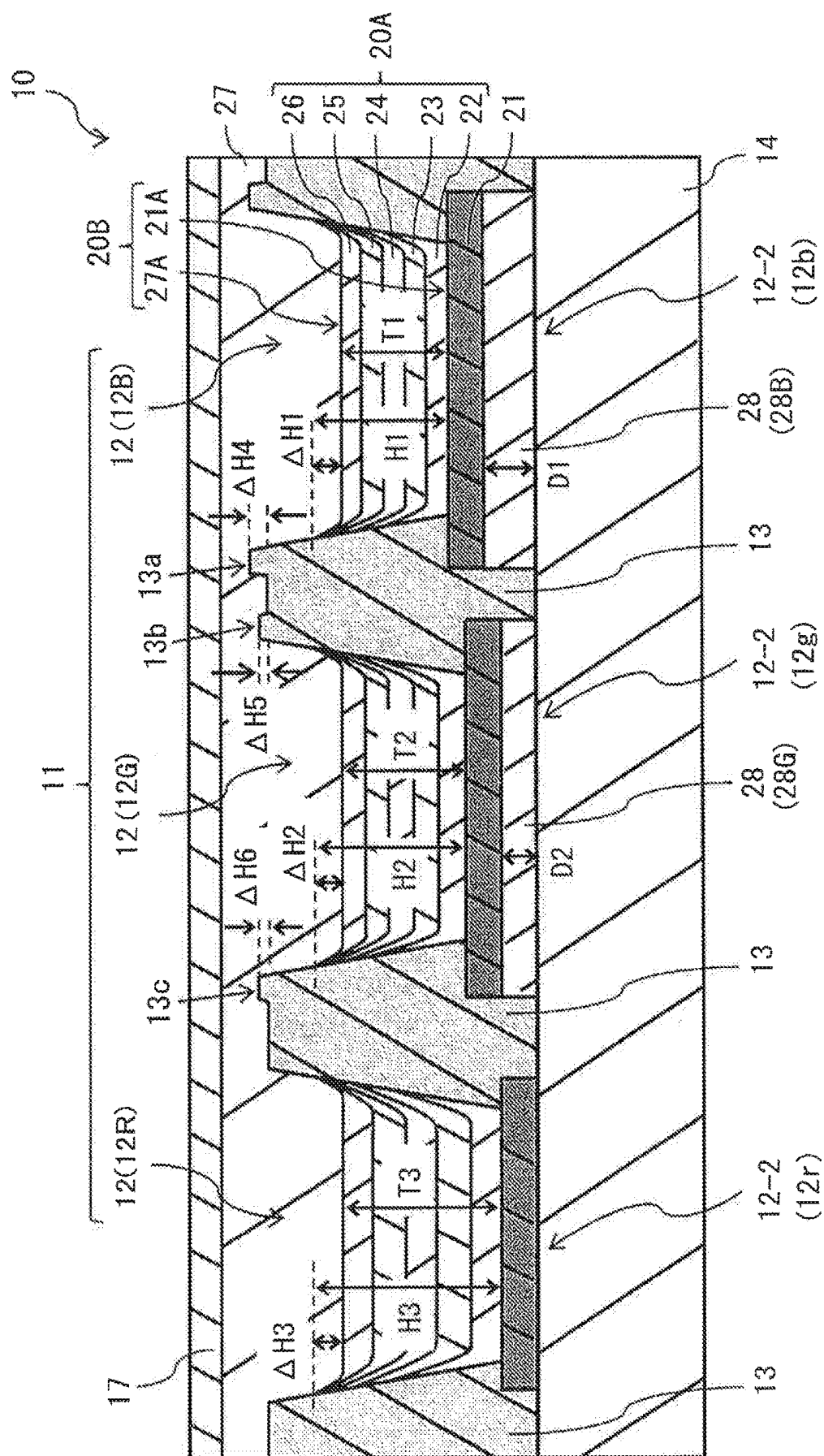
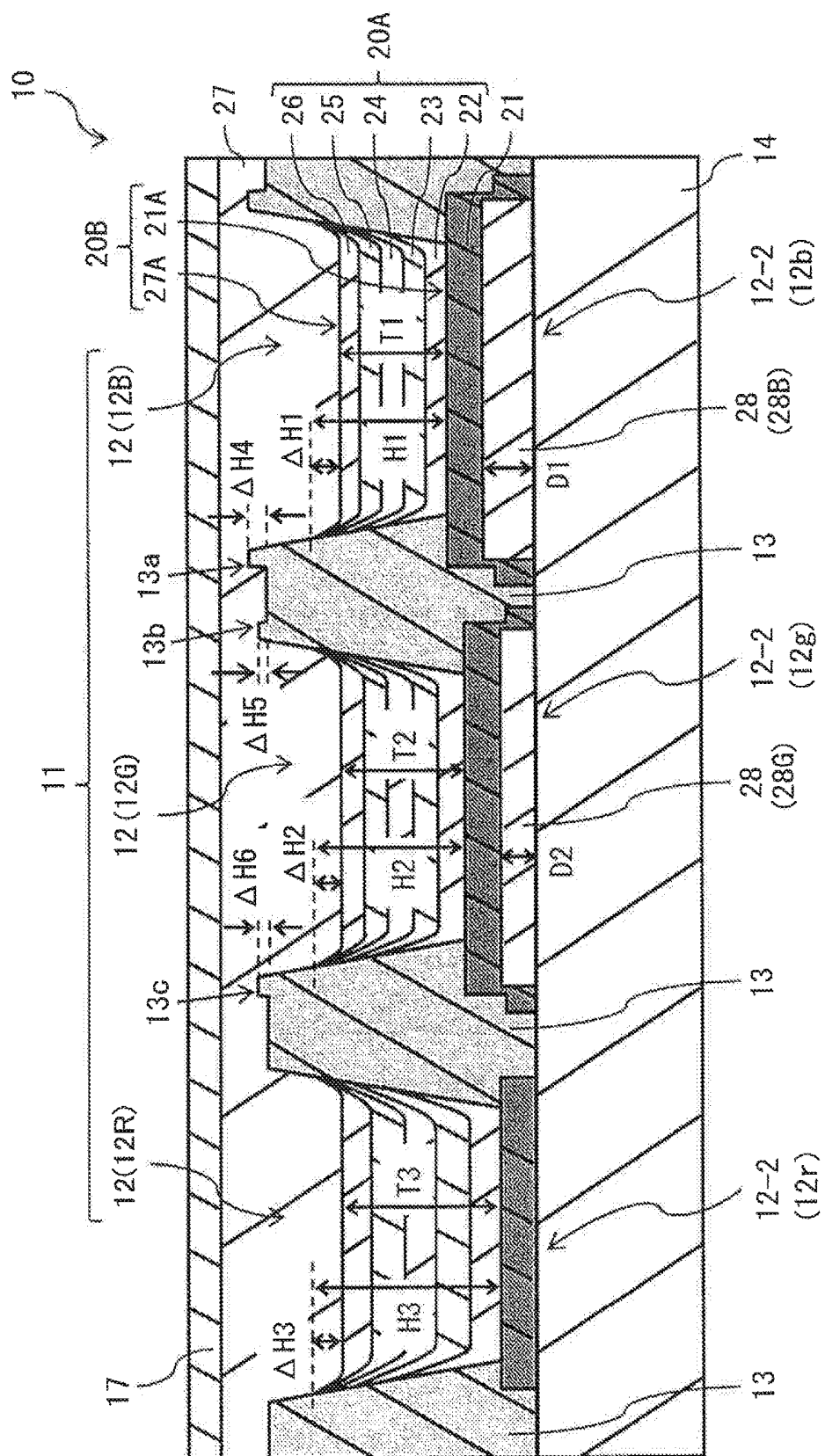


FIG. 11





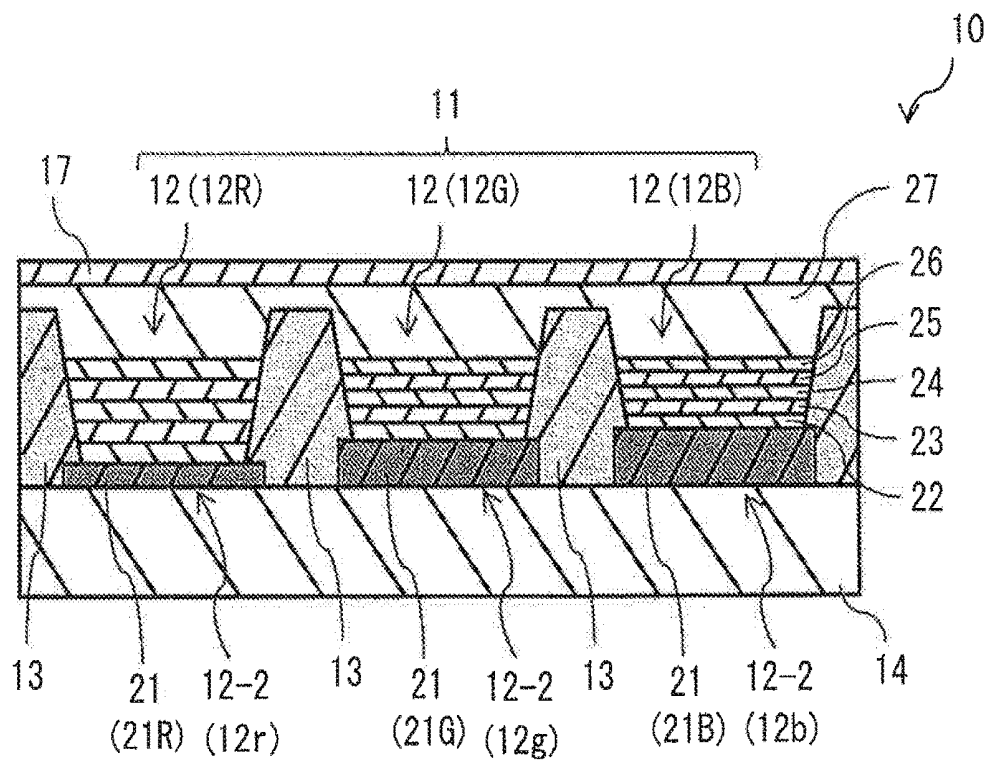


FIG. 14

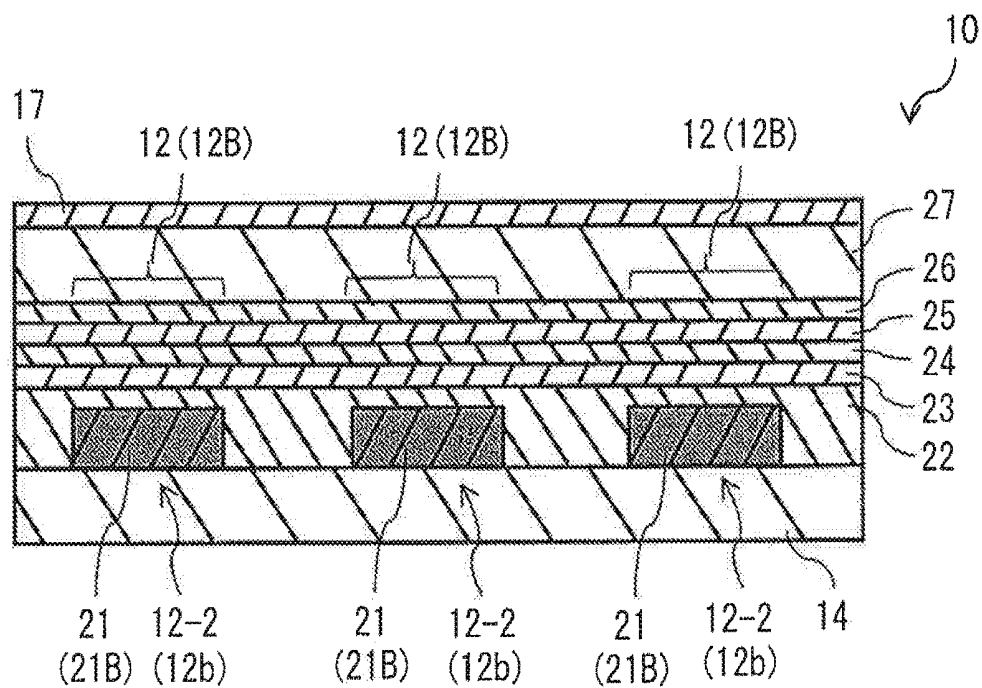


FIG. 15

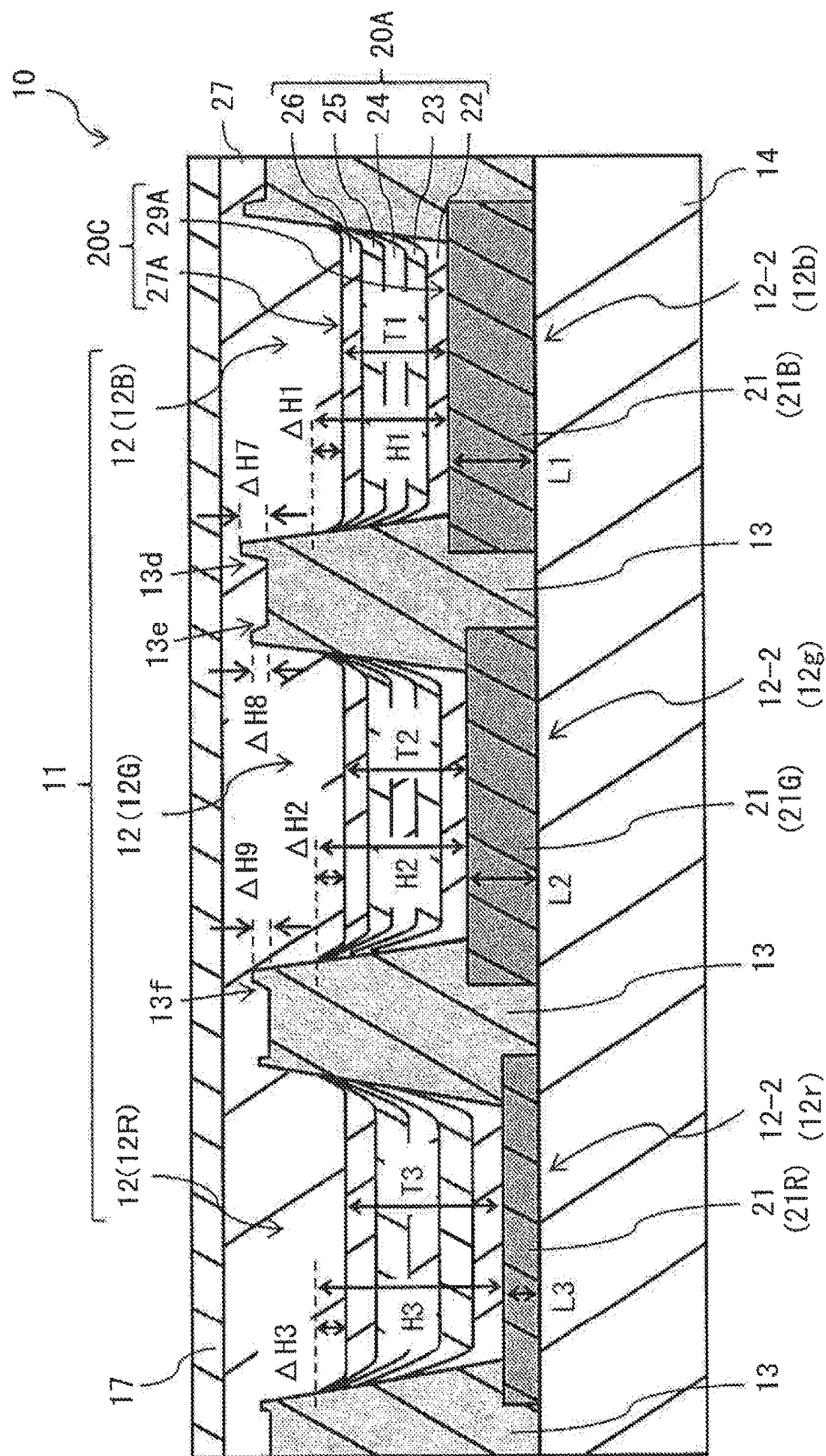
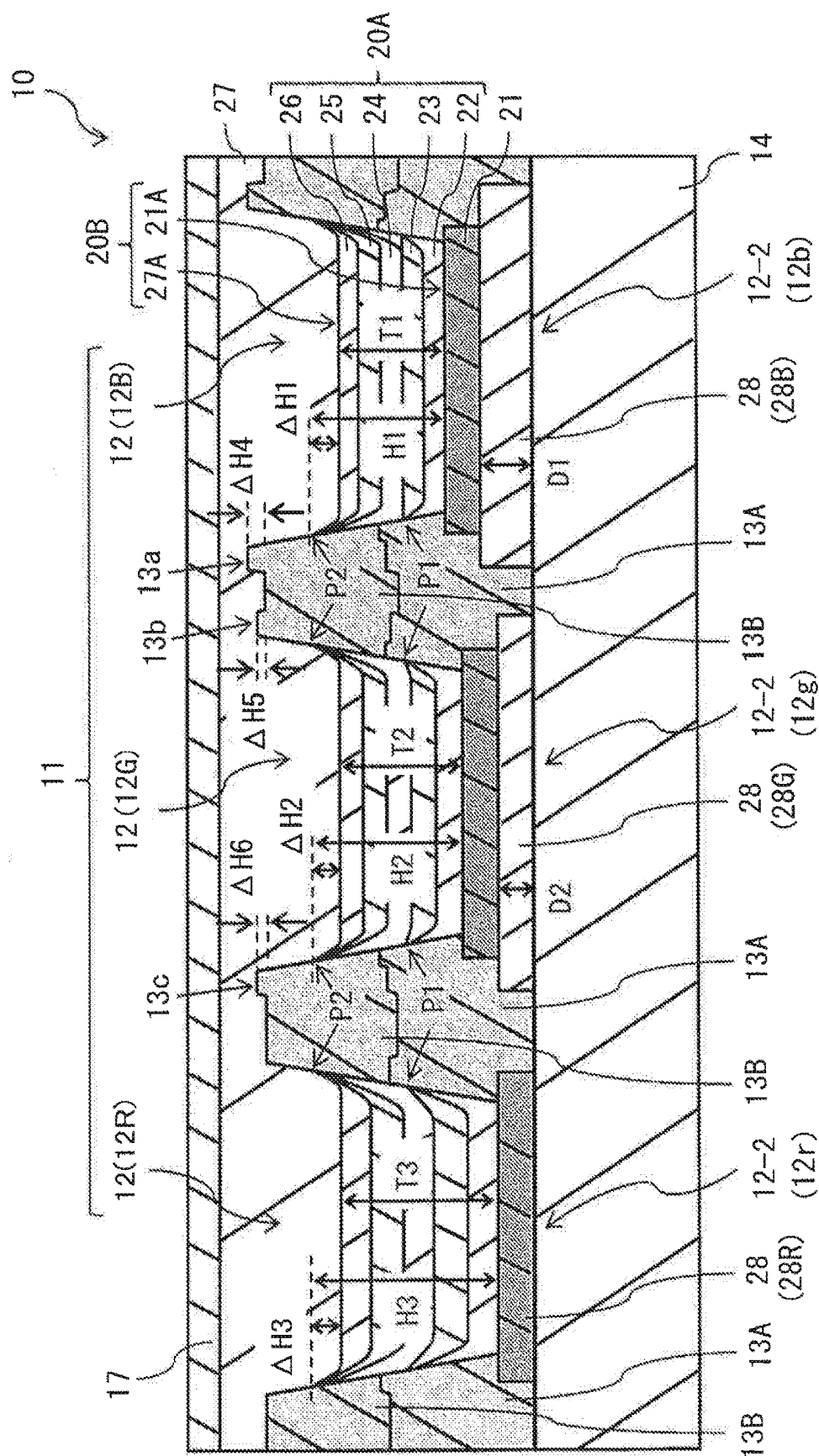


FIG. 16



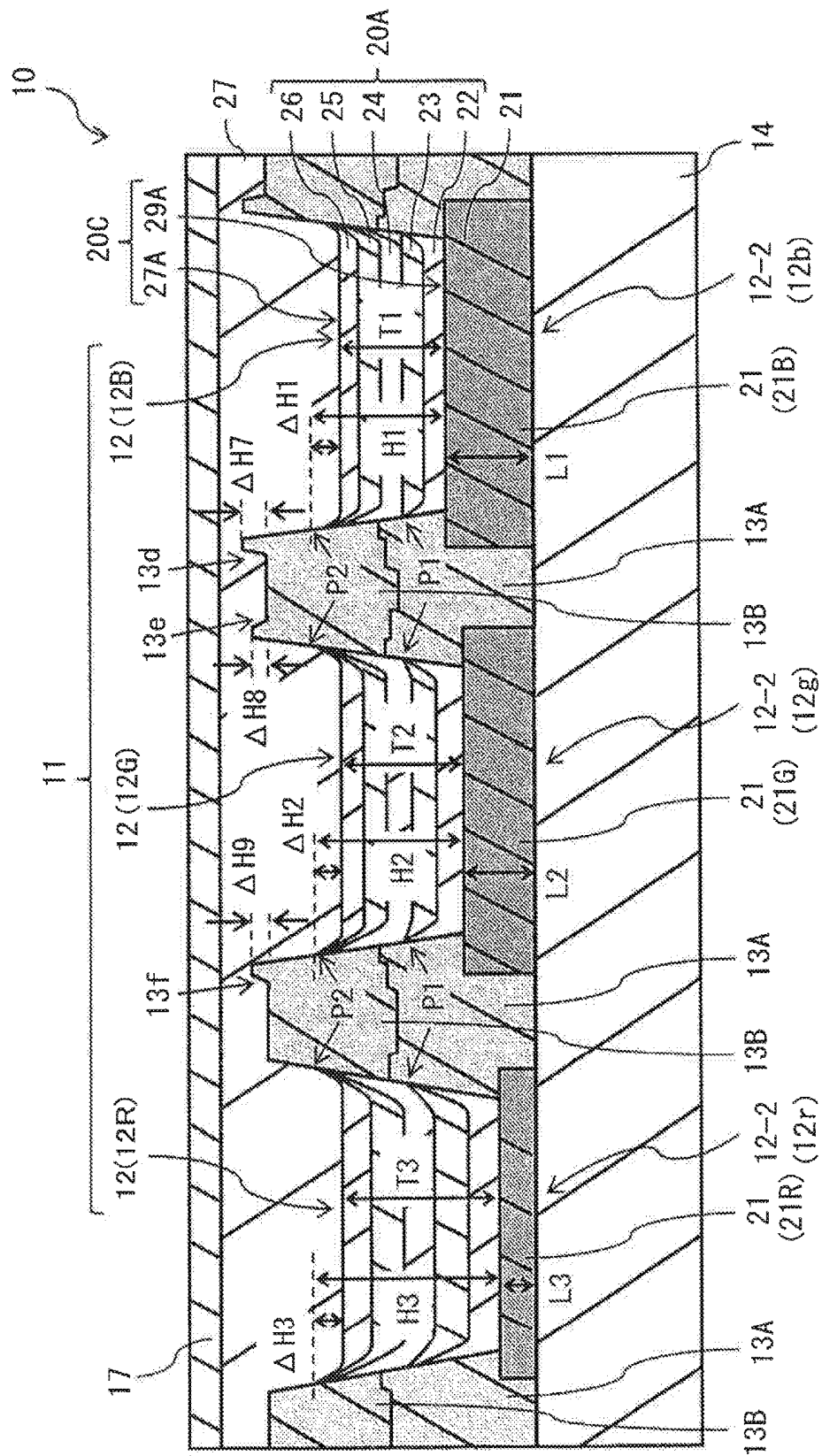


FIG. 18

**ORGANIC ELECTROLUMINESCENT
ELEMENT, ORGANIC
ELECTROLUMINESCENT PANEL, AND
LUMINESCENT UNIT**

CROSS REFERENCE TO RELATED
APPLICATIONS

[0001] This application claims the benefit of Japanese Priority Patent Application JP2017-038720 filed Mar. 1, 2017, the entire contents of which are incorporated herein by reference.

BACKGROUND

[0002] The disclosure relates to an organic electroluminescent element, an organic electroluminescent panel, and a luminescent unit.

[0003] There is known a method of manufacturing an organic electroluminescent panel by forming an organic electroluminescent element for each pixel with use of an ink jet device. A recent increase in definition has brought a reduction in pixel size and a reduction of a liquid amount to be retained per unit area. From the standpoint of solubility or a printable physical property such as viscosity, however, it is difficult to excessively increase an ink concentration. Note that the bank that defines each pixel is described in, for example, International Publication No. WO 2012/025954 and Japanese Unexamined Patent Application Publication No. 2008-243773, for example.

SUMMARY

[0004] In a case where a side of a bank is made lyophilic, however, a meniscus is formed on an ink surface in a process of drying ink. The meniscus is also formed on an upper surface of an ink layer after being dried. This makes a bank vicinity extremely thick in the ink layer, resulting in a phenomenon in which a center part of a pixel emits light strongly. As a result, a part that is usable as a light-emitting part is reduced.

[0005] It is desirable to provide an organic electroluminescent element, an organic electroluminescent panel, and a luminescent unit that make it possible to suppress a reduction of a part usable as a light-emitting part.

[0006] An organic electroluminescent element according to an embodiment of the disclosure includes: an organic electroluminescent part; and a pair of partition walls provided on both sides of the organic electroluminescent part. The organic electroluminescent part includes an organic material layer including a light-emitting layer that emits electroluminescence light, a resonator that is in contact with the organic material layer, and includes an anode-side reflecting surface and a cathode-side reflecting surface that face each other with the organic material layer provided therebetween, and a film-thickness adjustment layer provided at a position that is outside of the resonator and closer to the anode-side reflecting surface, and having a thickness that is adjusted to allow a difference between a height of a pinning position and a height of a middle position of an upper surface of the organic material layer to fall within a predetermined range. The pinning position is a position at which the upper surface of the organic material layer and each of the partition walls are in contact with each other.

[0007] An organic electroluminescent panel according to an embodiment of the disclosure includes a plurality of

pixels each including a plurality of subpixels. In each of the pixels, at least one of the subpixels includes an organic electroluminescent part, and a pair of partition walls provided on both sides of the organic electroluminescent part. The organic electroluminescent part includes an organic material layer including a light-emitting layer that emits electroluminescence light, a resonator that is in contact with the organic material layer, and includes an anode-side reflecting surface and a cathode-side reflecting surface that face each other with the organic material layer provided therebetween, and a film-thickness adjustment layer provided at a position that is outside of the resonator and closer to the anode-side reflecting surface, and having a thickness that is adjusted to allow a difference between a height of a pinning position and a height of a middle position of an upper surface of the organic material layer to fall within a predetermined range. The pinning position is a position at which the upper surface of the organic material layer and each of the partition walls are in contact with each other.

[0008] A luminescent unit according to an embodiment of the disclosure includes: an organic electroluminescent panel including a plurality of pixels; and a driver that drives the plurality of pixels. The plurality of pixels each include a plurality of subpixels. In each of the pixels, at least one of the subpixels includes an organic electroluminescent part, and a pair of partition walls provided on both sides of the organic electroluminescent part. The organic electroluminescent part includes an organic material layer including a light-emitting layer that emits electroluminescence light, a resonator that is in contact with the organic material layer, and includes an anode-side reflecting surface and a cathode-side reflecting surface that face each other with the organic material layer provided therebetween, and a film-thickness adjustment layer provided at a position that is outside of the resonator and closer to the anode-side reflecting surface, and having a thickness that is adjusted to allow a difference between a height of a pinning position and a height of a middle position of an upper surface of the organic material layer to fall within a predetermined range. The pinning position is a position at which the upper surface of the organic material layer and each of the partition walls are in contact with each other.

BRIEF DESCRIPTION OF THE DRAWINGS

[0009] FIG. 1 is a view illustrating a schematic configuration example of an organic electroluminescent unit according to an embodiment of the disclosure.

[0010] FIG. 2 is a view illustrating a circuit configuration example of subpixels included in each pixel of FIG. 1.

[0011] FIG. 3 is a view illustrating a schematic configuration example of an organic electroluminescent panel of FIG. 1.

[0012] FIG. 4 is a view illustrating a cross-sectional configuration example, taken along a line A-A, of the organic electroluminescent panel of FIG. 3.

[0013] FIG. 5 is a view illustrating a cross-sectional configuration example, taken along a line B-B, of the organic electroluminescent panel of FIG. 3.

[0014] FIG. 6 is an enlarged view of a cross-sectional configuration example of the organic electroluminescent panel of FIG. 4.

[0015] FIG. 7 is an enlarged view of a cross-sectional configuration example of an organic electroluminescent element of FIG. 4.

[0016] FIG. 8 is a view illustrating a relationship between a difference and a rate of planarization.

[0017] FIG. 9A is a view illustrating an example of a manufacturing process of the organic electroluminescent panel of FIG. 4.

[0018] FIG. 9B is a view illustrating an example of a manufacturing process following FIG. 9A.

[0019] FIG. 9C is a view illustrating an example of a manufacturing process following FIG. 9B.

[0020] FIG. 10 is a view illustrating a modification example of the cross-sectional configuration of the organic electroluminescent panel of FIG. 4.

[0021] FIG. 11 is a view illustrating a modification example of the cross-sectional configuration of the organic electroluminescent panel of FIG. 4.

[0022] FIG. 12 is a view illustrating a modification example of a cross-sectional configuration of the organic electroluminescent panel of FIG. 6.

[0023] FIG. 13 is a view illustrating a modification example of the cross-sectional configuration of the organic electroluminescent panel of FIG. 6.

[0024] FIG. 14 is a view illustrating a modification example of the cross-sectional configuration of the organic electroluminescent panel of FIG. 4.

[0025] FIG. 15 is a view illustrating a modification example of a cross-sectional configuration of the organic electroluminescent panel of FIG. 5.

[0026] FIG. 16 is a view illustrating a modification example of the cross-sectional configuration of the organic electroluminescent panel of FIG. 6.

[0027] FIG. 17 is a view illustrating a modification example of the cross-sectional configuration of the organic electroluminescent panel of FIG. 6.

[0028] FIG. 18 is a view illustrating a modification example of a cross-sectional configuration of the organic electroluminescent panel of FIG. 16.

DETAILED DESCRIPTION

[0029] In the following, some example embodiments of the disclosure are described in detail, in the following order, with reference to the accompanying drawings. Note that the following description is directed to illustrative examples of the disclosure and not to be construed as limiting to the technology. Factors including, without limitation, numerical values, shapes, materials, components, positions of the components, and how the components are coupled to each other are illustrative only and not to be construed as limiting to the technology. Further, elements in the following example embodiments which are not recited in a most-generic independent claim of the disclosure are optional and may be provided on an as-needed basis. The drawings are schematic and are not intended to be drawn to scale. Note that the like elements are denoted with the same reference numerals, and any redundant description thereof will not be described in detail.

Embodiments

[Configuration]

[0030] FIG. 1 illustrates a schematic configuration example of an organic electroluminescent unit 1 according to an embodiment of the disclosure. FIG. 2 illustrates an example of a circuit configuration of a subpixel 12 included

in each pixel 11 that is provided in the organic electroluminescent unit 1. The organic electroluminescent unit 1 may include an organic electroluminescent panel 10, a controller 20, and a driver 30, for example. The driver 30 may be implemented on an outer edge of the organic electroluminescent panel 10. The organic electroluminescent panel 10 may have a plurality of pixels 11 disposed in matrix. The controller 20 and the driver 30 may drive the organic electroluminescent panel 10, i.e., drive the plurality of pixels 11, on the basis of an image signal Din and a synchronization signal Tin. The image signal Din and the synchronization signal Tin may be inputted from outside.

(Organic Electroluminescent Panel 10)

[0031] Each of the pixels 11 may be active-matrix-driven by the controller 20 and the driver 30. Thereby, the organic electroluminescent panel 10 may display an image based on the image signal Din and the synchronization signal Tin that are inputted from the outside. The organic electroluminescent panel 10 may have a plurality of scan lines WSLs extending in a row direction, a plurality of signal lines DTLs and a plurality of power lines DSLs both extending in a column direction, and the plurality of pixels 11 that are disposed in matrix.

[0032] The scan lines WSLs may be used to select the respective pixels 11. The scan lines WSL may supply the respective pixels 11 with a selection pulse that selects the pixels 11 on a predetermined unit basis, such as a pixel row basis, for example. The signal lines DTLs may be used to supply a signal voltage Vsig to the respective pixels 11. The signal voltage Vsig may be based on the image signal Din. The signal lines DTLs may supply a data pulse including the signal voltage Vsig to the respective pixels 11. The power lines DSLs may supply electric power to the respective pixels 11.

[0033] Each of the pixels 11 may include a subpixel 12 that emits red light, a subpixel 12 that emits green light, and a subpixel 12 that emits blue light, for example. Furthermore, each of the pixels 11 may also include a subpixel 12 that emits light of any other color, which may be white or yellow, for example. In each of the pixels 11, the subpixels 12 may be arranged in a line in a predetermined direction, for example.

[0034] Each of the signal lines DTLs may be coupled to an output end of a horizontal selector 31 to be described later. The signal lines DTLs, for example, may be each assigned to corresponding one of pixel columns. Each of the scan lines WSLs may be coupled to an output end of a write scanner 32 to be described later. The scan lines WSLs, for example, may be each assigned to corresponding one of pixel rows. Each of the power lines DSLs may be coupled to an output end of a power supply. The power lines DSLs, for example, may be each assigned to corresponding one of the pixel rows.

[0035] Each of the subpixels 12 may have a pixel circuit 12-1 and an organic electroluminescent element 12-2. The organic electroluminescent element 12-2 may correspond to a specific example of an “organic electroluminescent unit” in one embodiment of the disclosure. A configuration of the organic electroluminescent element 12-2 is described later in detail.

[0036] The pixel circuit 12-1 may control light emission and light extinction of the organic electroluminescent element 12-2. The pixel circuit 12-1 may hold a voltage written

into corresponding one of the subpixels **12** through write scan. The write scan is described later. The pixel circuit **12-1** may include a driving transistor **Tr1**, a switching transistor **Tr2**, and a storage capacitor **Cs**, for example.

[0037] The switching transistor **Tr2** may control application of the signal voltage **Vsig** to a gate of the driving transistor **Tr1**. The signal voltage **Vsig** may correspond to the image signal **Din**. For example, the switching transistor **Tr2** may perform sampling of a voltage of the signal line **DTL** and write the voltage obtained through the sampling to the gate of the driving transistor **Tr1**. The driving transistor **Tr1** may be coupled in series to the organic electroluminescent element **12-2**. The driving transistor **Tr1** may drive the organic electroluminescent element **12-2**. The driving transistor **Tr1** may control an electric current flowing through the organic electroluminescent element **12-2** in accordance with a magnitude of the voltage sampled by the switching transistor **Tr2**. The storage capacitor **Cs** may store a predetermined voltage between a gate and a source of the driving transistor **Tr1**. The storage capacitor **Cs** may keep a gate-source voltage **Vgs** of the driving transistor **Tr1** constant for a predetermined period of time. Note that the pixel circuit **12-1** may have a circuit configuration in which various capacitors or transistors are added to a circuit of **2Tr1C** described above. Alternatively, the pixel circuit **12-1** may have a different circuit configuration from the circuit configuration of the **2Tr1C** described above.

[0038] Each of the signal lines **DTLs** may be coupled to an output end of the horizontal selector **31** and to a source or a drain of the switching transistor **Tr2**. The horizontal selector **31** is described later. Each of the scan lines **WSLs** may be coupled to the output end of the write scanner **32** and to a gate of the switching transistor **Tr2**. The write scanner **32** is described below. Each of the power lines **DSLs** may be coupled to a power circuit and the source or a drain of the driving transistor **Tr1**.

[0039] The gate of the switching transistor **Tr2** may be coupled to the scan line **WSL**. The source or the drain of the switching transistor **Tr2** may be coupled to the signal line **DTL**. Of the source and the drain of the switching transistor **Tr2**, a terminal not coupled to the signal line **DTL** may be coupled to the gate of the driving transistor **Tr1**. The source or the drain of the driving transistor **Tr1** may be coupled to the power line **DSL**. Of the source and the drain of the driving transistor **Tr1**, a terminal not coupled to the power line **DSL** may be coupled to an anode **21** of the organic electroluminescent element **12-2**. One end of the storage capacitor **Cs** may be coupled to the gate of the driving transistor **Tr1**. Other end of the storage capacitor **Cs** may be coupled to a terminal on the side of the organic electroluminescent element **12-2** of the source and the drain of the driving transistor **Tr1**.

(Driver **30**)

[0040] The driver **30** may have the horizontal selector **31** and the write scanner **32**, for example. In response to, or in synchronization with, input of a control signal, for example, the horizontal selector **31** may apply the analog signal voltage **Vsig** to each of the signal lines **DTLs**. The analog signal voltage **Vsig** may be inputted from the controller **20**. The write scanner **32** may scan the plurality of subpixels **12** on a predetermined unit basis.

(Controller **20**)

[0041] The controller **20** is described in the following. The controller **20** may perform a predetermined correction on the digital image signal **Din** and generate the signal voltage **Vsig** on the basis of the thus-obtained image signal. The image signal **Din** may be inputted from the outside, for example. The controller **20** may output the generated signal voltage **Vsig** to the horizontal selector **31**, for example. In response to, or in synchronization with, the synchronization signal **Tin**, the controller **20** may output a control signal to each circuit in the driver **30**. The synchronization signal may be inputted from the outside, for example.

[0042] The organic electroluminescent element **12-2** is described hereinafter with reference to FIG. 3, FIG. 4, FIG. 5, and FIG. 6. FIG. 3 illustrates a schematic configuration example of the organic electroluminescent panel **10**. FIG. 4 illustrates a cross-sectional configuration example of the organic electroluminescent panel **10** taken along a line A-A of FIG. 3. FIG. 5 illustrates a cross-sectional configuration example of the organic electroluminescent panel **10** taken along a line B-B of FIG. 3. FIG. 6 is an enlarged view illustrating a cross-sectional configuration example of the organic electroluminescent element **12-2** of FIG. 4.

[0043] The organic electroluminescent panel **10** may have the plurality of pixels **11** arranged in matrix. As described above, each of the pixels **11** may include the subpixel **12** (**12R**) that emits red light, the subpixel **12** (**12G**) that emits green light, and the subpixel **12** (**12B**) that emits blue light, for example. The subpixel **12R** may include the organic electroluminescent element **12-2** (**12r**) that emits red light. The subpixel **12G** may include the organic electroluminescent element **12-2** (**12g**) that emits green light. The subpixel **12B** may include the organic electroluminescent element **12-2** (**12b**) that emits blue light. The subpixels **12R**, **12G**, and **12B** may be arranged in stripes, for example. For example, in each of the pixels **11**, the subpixels **12R**, **12G**, and **12B** may be disposed in the column direction. Furthermore, in each pixel row, the plurality of subpixels **12** that emit pieces of light of the same color may be disposed in the row direction, for example.

[0044] The organic electroluminescent panel **10** may have, on a substrate **14**, a plurality of line banks **13** extending in the row direction. The line banks **13** may correspond to a specific example of “partition walls” in one embodiment of the disclosure. The plurality of line banks **13** may define the subpixels **12** in each of the pixels **11**. The organic electroluminescent panel **10** may further have a plurality of banks **15** on the substrate **14**. The plurality of banks **15** may have ends of the plurality of line banks **13** attached to each other. Each of the banks **15** may extend in the column direction. The substrate **14** may include a base member and a wiring layer. The base member may support, without limitation, each of the organic electroluminescent elements **12-2** and each of the line banks **13**, for example. The wiring layer may be provided on the base member. The base member in the substrate **14** may include, without limitation, a glass substrate or a flexible substrate, for example. Non-limiting examples of a material of the glass substrate used as the base member in the substrate **14** may include alkali-free glass, soda glass, non-fluorescent glass, phosphate glass, boric acid glass, or quartz, for example. Non-limiting examples of a material of the flexible substrate used as the base member in the substrate **14** may include acrylic-based resin, styrene-based resin, polycarbonate-based resin, epoxy-based resin,

polyethylene, polyester, or silicone-based resin, for example. The wiring layer in the substrate 14 may include the pixel circuit 12-1 of each of the pixels 11, for example.

[0045] The line banks 13 and the banks 15 may include an insulating organic material, for example. The insulating organic material may include but not limited to acrylic-based resin, polyimide-based resin, or novolac-based phenolic resin. The line banks 13 and the banks 15 may include, for example, insulating resin that is heat-resistant and resistant to a solvent. The line banks 13 and the banks 15 may be formed by processing, for example, insulating resin into a predetermined pattern through photolithography and development. A cross-sectional shape of the line bank 13 may be of a forward taper type as illustrated in FIG. 4 or of a backward taper type in which a hem is narrow.

[0046] A region surrounded by two of the line banks 13 that are mutually parallel and adjacent to each other and by the banks 15 at both ends may be a groove 16. In each of the subpixels 12, one of the organic electroluminescent elements 12-2 may be disposed in a gap of the two line banks 13 that are mutually parallel and adjacent to each other. For example, in each of the subpixels 12, one of the organic electroluminescent elements 12-2 may be disposed in the groove 16. Each of the organic electroluminescent elements 12-2 may have, for example, the anode 21, a hole-injection layer 22, a hole-transport layer 23, an organic light-emitting layer 24, an electron-transport layer 25, an electron-injection layer 26, and a cathode 27 in this order from a side of the substrate 14. A laminate 20A that includes the hole-injection layer 22, the hole-transport layer 23, the organic light-emitting layer 24, the electron-transport layer 25, and the electron-injection layer 26 may correspond to a specific example of an "organic material layer" in one embodiment of the disclosure. The organic light-emitting layer 24 may correspond to a specific example of a "light-emitting layer" in one embodiment of the disclosure. The anode 21 may correspond to a specific example of an "anode electrode" in one embodiment of the disclosure.

[0047] Each of the organic electroluminescent elements 12-2 may have the laminate 20A that includes the organic light-emitting layer 24. The organic light-emitting layer 24 may emit electroluminescence light. Furthermore, each of the organic electroluminescent elements 12-2 may have a resonator 20B. The resonator 20B may be in contact with the laminate 20A and include a reflecting surface 21A and a reflecting surface 27A, for example. The reflecting surfaces 21A and 27A may be disposed to face each other with the laminate 20A provided therebetween. In one embodiment, the reflecting surface 21A may be an upper surface of the anode 21 and a surface of the anode 21 that is in contact with the laminate 20A. The reflecting surface 27A may be a lower surface of the cathode 27 and a surface of the cathode 27 that is in contact with the laminate 20A. The resonator 20B is provided to obtain a sharp emission spectrum, making use of a resonance phenomenon of light. The resonator 20B may repeatedly reflect electroluminescence light emitted from the organic light-emitting layer 24 and generate a standing wave. The standing wave may be stable only in a certain wavelength. The standing wave may be generated when an optical path length of the resonator 20B is an integral multiple of a half-wavelength.

[0048] The hole-injection layer 22 may improve hole injection efficiency. The hole-transport layer 23 may transport, to the organic light-emitting layer 24, holes injected

from the anode 21. The organic light-emitting layer 24 may emit electroluminescence light of a predetermined color through a recombination of electrons and holes. The electron-transport layer 25 may transport, to the organic light-emitting layer 24, electrons injected from the cathode 27. The electron-injection layer 26 may improve electron injection efficiency. The hole-injection layer 22, the electron-injection layer 26, or both may be omitted. Each of the organic electroluminescent elements 12-2 may further have any layer other than those mentioned above.

[0049] The anode 21 may be disposed on the substrate 14, for example. Furthermore, the anode 21 may be so disposed that edges of the anode 21 are embedded in the line banks 13, for example. Thus, at least a part of the edges of the anode 21 may be located immediately below each of the line banks 13. In one subpixel row, the anodes 21 may be equally spaced in a direction in which the groove 16 extends, for example. The anode 21 may be a reflecting electrode that has reflectivity, for example. The anode 21 may be a reflecting conducting film that includes an electrically-conducting material such as but not limited to aluminum (Al), silver (Ag), or an alloy of aluminum or silver. For example, in this case, the reflecting surface 21A of the anode 21 may be an anode reflecting surface. Alternatively, the anode 21 may have a configuration in which a reflecting electrode is stacked on a transparent electrode, for example. Furthermore, the anode 21 may be a reflecting electrode that has translucency. In this case, the anode 21 may include a transparent conducting film and an Al thin film. The transparent conducting film may include a transparent conducting material such as but not limited to Indium Tin Oxide (ITO) or Indium Zinc Oxide (IZO). The Al thin film may be disposed on a surface of the transparent conducting film. In such an example, the reflecting surface 21A of the anode 21 may be an anode semi-transmissive surface.

[0050] In a case where the anode 21 is the reflecting electrode that has reflectivity, the cathode 27 may be a reflecting electrode that is semi-transmissive. In such an example, the cathode 27 may include a transparent conducting film and an Al thin film. The transparent conducting film may include a transparent conducting material such as but not limited to ITO or IZO. The Al thin film may be disposed on a surface of the transparent conducting film. In such an example, the reflecting surface 27A of the cathode 27 may be a cathode semi-transmissive surface. In a case where the anode 21 is a reflecting electrode that has translucency, the cathode 27 may be a reflecting electrode that has reflectivity. In such an example, the cathode 27 may include but not limited to aluminum (Al), magnesium (Mg), silver (Ag), an aluminum-lithium alloy, or a magnesium-silver alloy, for example. In such an example, the reflecting surface 27A of the cathode 27 may be a cathode reflecting surface. In a case where the substrate 14 and the anode 21 have translucency and the cathode 27 has reflectivity, the organic electroluminescent element 12-2 may have a bottom emission structure in which the organic electroluminescent element 12-2 emits light from the side of the substrate 14. In a case where the anode 21 has reflectivity and the cathode 27 has translucency, the organic electroluminescent element 12-2 may have a top emission structure in which the organic electroluminescent element 12-2 emits light from a side of the cathode 27.

[0051] The hole-injection layer 22 may facilitate injection of holes from the anode 21 to the organic light-emitting layer

24. The hole-injection layer **22** may include an oxide of, for example but not limited to, silver (Ag), molybdenum (Mo), chromium (Cr), vanadium (V), tungsten (W), nickel (Ni), or iridium (Ir), or a conductive polymer material such as PEDOT. PEDOT is a mixture of polythiophene and polystyrene sulfonate.

[0052] The hole-transport layer **23** may transport, to the organic light-emitting layer **24**, the holes injected from the anode **21**. The hole-transport layer **23** may be a coated film, for example. The hole-transport layer **23** may be provided by application and drying of a solution a solute of which has an organic material, for example, as a main component. The organic material may have hole transportability and may be hereinafter referred to as a “hole transportability material **23M**”. The hole-transport layer **23** may include the hole transportability material **23M** as a main component.

[0053] The hole transportability material **23M** may be a basic ingredient, namely a material, of the hole-transport layer **23**. The hole transportability material **23M** may be for example but not limited to arylamine derivatives, triazole derivatives, oxadiazole derivatives, imidazole derivatives, polyarylethane derivatives, pyrazoline derivatives and pyrazole derivatives, phenylenediamine derivatives, amino-substituted chalcone derivatives, oxazole derivatives, styryl anthracene derivatives, fluorenone derivatives, hydrazone derivatives, stilbene derivatives, butadiene compounds, polystyrene derivatives, triphenylmethane derivatives, and tetraphenyl benzene derivatives, or a material including a combination thereof. The hole transportability material **23M** may further have, in its molecular architecture, a soluble group and an insoluble group for solubility and insolubilization features, for example. The insoluble group may be, without limitation, a thermal dissociation soluble group, a crosslinking group, or a desorption protecting group.

[0054] The organic light-emitting layer **24** may emit light of a predetermined color through the recombination of holes and electrons. The organic light-emitting layer **24** may be a coating layer. The organic light-emitting layer **24** may be provided by application and drying of a solution a solute of which has an organic material as a main component. The organic material may generate an exciter from the recombination of holes and electrons and emit light. The organic material may be hereinafter referred to as an “organic light-emitting material **24M**”. The organic light-emitting layer **24** may include the organic light-emitting material **24M** as a main component. In the organic electroluminescent element **12r** included in the subpixel **12R**, the organic light-emitting material **24M** may include an organic red light-emitting material. In the organic electroluminescent element **12g** included in the subpixel **12G**, the organic light-emitting material **24M** may include an organic green light-emitting material. In the organic electroluminescent element **12b** included in the subpixel **12B**, the organic light-emitting material **24M** may include an organic blue light-emitting material.

[0055] The organic light-emitting layer **24** may include a single-layered organic light-emitting layer or a plurality of organic light-emitting layers that are laminated, for example. In a case where the organic light-emitting layer **24** is the plurality of organic light-emitting layers in which the organic light-emitting layers **24** are laminated, the organic light-emitting layer **24** may be a laminate of the plurality of organic light-emitting layers main components of which are common to each other, for example. In such an example,

each of the organic light-emitting layers may be a coating layer. Each of the organic light-emitting layers may be provided by application and drying of a solution a solute of which has the organic light-emitting material **24M** as a main component.

[0056] The organic light-emitting material **24M** may be a basic ingredient, namely a material, of the organic light-emitting layer **24**. While the organic light-emitting material **24M** may be for example a single dopant material, the organic light-emitting material **24M** may include a combination of a host material and a dopant material in one example. In other words, the organic light-emitting layer **24** may include the host material and the dopant material as the organic light-emitting material **24M**. The host material may mainly serve to transport charges of electrons or holes, while the dopant material may serve to emit light. The host material and the dopant material may not be limited to only one kind, but may be a combination of two or more kinds. An amount of the dopant material may be equal to or greater than 0.01 weight percent and equal to or smaller than 30 weight percent with respect to the host material. In one example, the amount of the dopant material may be equal to or greater than 0.01 weight percent and equal to or smaller than 10 weight percent.

[0057] For example, amine compounds, condensed polyaromatic compounds, or hetero ring compounds may be used as the host material of the organic light-emitting layer **24**. For example, monoamine derivatives, diamine derivatives, triamine derivatives, or tetraamine derivatives, without limitation, may be used as the amine compounds. For example, the condensed polyaromatic compounds may include but not limited to anthracene derivatives, naphthalene derivatives, naphthacene derivatives, phenanthrene derivatives, chrysene derivatives, fluoranthene derivatives, triphenylene derivatives, pentacene derivatives, or perylene derivatives. For example, the hetero ring compounds may include but not limited to carbazole derivatives, furan derivatives, pyridine derivatives, pyrimidine derivatives, triazine derivatives, imidazole derivatives, pyrazole derivatives, triazole derivatives, oxazole derivatives, oxadiazole derivatives, pyrrole derivatives, indole derivatives, azaindole derivatives, azacarbazole derivatives, pyrazoline derivatives, pyrazolone derivatives, or phthalocyanine derivatives.

[0058] In addition, for example, pyrene derivatives, fluoranthene derivatives, arylacetylene derivatives, fluorene derivatives, perylene derivatives, oxadiazole derivatives, anthracene derivatives, or chrysene derivatives may also be used as the dopant material for the organic light-emitting layer **24**. A metal complex may also be used as the dopant material for the organic light-emitting layer **24**. The metal complex may include a metal complex having a ligand and a metallic atom such as but not limited to iridium (Ir), platinum (Pt), osmium (Os), gold (Au), rhenium (Re), or ruthenium (Ru).

[0059] The electron-transport layer **25** may transport, to the organic light-emitting layer **24**, electrons injected from the cathode **27**. The electron-transport layer **25** may be a coated film, for example. The electron-transport layer **25** may include an organic material having electron transportability as a main component. The organic material may be hereinafter referred to as an “electron transportability material **25M**”.

[0060] The electron-transport layer **25** may be provided between the organic light-emitting layer **24** and the cathode **27**, and may transport, to the organic light-emitting layer **24**, electrons injected from the cathode **27**. The electron transportability material **25M** may be a basic ingredient, namely a material, of the electron-transport layer **25**. The electron transportability material **25M** may be aromatic hetero ring compounds, for example, that has one or more heteroatoms in a molecule. The aromatic hetero ring compounds may include a compound having a skeleton that includes but not limited to a pyridine ring, a pyrimidine ring, a triazine ring, a benzimidazole ring, a phenanthroline ring, or a quinazoline ring, for example. The electron-transport layer **25** may also include metal having the electron transportability. Inclusion of the metal having the electron transportability enables improved electron transportability of the electron-transport layer **25**. For example, barium (Ba), lithium (Li), calcium (Ca), potassium (K), cesium (Cs), sodium (Na), rubidium (Rb), or ytterbium (Yb), without limitation, may be used as metal included in the electron-transport layer **25**.

[0061] The organic electroluminescent panel **10** may further have a sealing layer **17** that seals each of the organic electroluminescent elements **12-2**, for example. The sealing layer **17** may be provided in contact with an upper surface of the cathode **27** of each of the organic electroluminescent elements **12-2**.

[0062] In the following, the film-thickness adjustment layer **28** is described.

[0063] In each of the pixels **11**, the organic electroluminescent element **12-2** included in at least one of the plurality of subpixels **12** may have the film-thickness adjustment layer **28**. FIG. 4 exemplarily illustrates one embodiment in which the film-thickness adjustment layer **28** is provided for the organic electroluminescent element **12-2** (**12g**) and the organic electroluminescent element **12-2** (**12b**). In FIG. 4, the film-thickness adjustment layer **28G** may be provided for the organic electroluminescent element **12-2** (**12g**), and the film-thickness adjustment layer **28B** may be provided for the organic electroluminescent element **12-2** (**12b**). In the following description, one embodiment is described in which the film-thickness adjustment layer **28** is provided only for the organic electroluminescent element **12-2** (**12g**) and the organic electroluminescent element **12-2** (**12b**).

[0064] The film-thickness adjustment layer **28** may be provided at a position that is outside of the resonator **20B** and closer to the reflecting surface **21A**. Thus, the film-thickness adjustment layer **28** may not lie in the resonator **20B** and may not be intended for optical adjustment of the resonator **20B**. The film-thickness adjustment layer **28** may be located immediately below the anode **21**. For example, the film-thickness adjustment layer **28** may be disposed between the substrate **14** and the anode **21**. The film-thickness adjustment layer **28** may adjust a distance of the reflecting surface **21A** of the anode **21** from the substrate **14**. For example, the film-thickness adjustment layer **28B** may have a thickness that is adjusted to allow a difference ΔH between a height H of a pinning position and a height T at a middle position of an upper surface of the laminate **20A** to fall within a predetermined range. The difference ΔH may be $\Delta H1$. The height H may be $H1$. The height T may be $T1$. The laminate **20A** may be the electron-injection layer **26**, for example. The pinning position is where the upper surface of the laminate **20A**, which may be the electron-injection layer **26**, for example, and the line bank **13** may be in contact with

each other. The film-thickness adjustment layer **28G** may have a thickness that is adjusted to allow a difference ΔH between a height H of a pinning position and a height T at the middle position of the upper surface of the laminate **20A** to fall within a predetermined range. The difference ΔH may be $\Delta H2$. The height H may be $H2$. The height T may be $T2$. The laminate **20A** may be the electron-injection layer **26**, for example. The pinning position is where the upper surface of the laminate **20A**, which may be the electron-injection layer **26**, for example, and the line bank **13** may be in contact with each other. A thickness of the anode **21** in the organic electroluminescent element **12-2** (**12r**) may be adjusted to allow a difference ΔH between a height H at a pinning position on the subpixel **12R** and a height T at the middle position of the upper surface of the laminate **20A** to fall within a predetermined range. The difference ΔH may be $\Delta H3$. The height H may be $H3$. The height T may be $T3$. The laminate **20A** may be the electron-injection layer **26**, for example. Furthermore, the pinning position may correspond to a boundary position between a lyophilic region and a liquid-repellent region on a side face of the line bank **13**.

[0065] An upper limit of the difference ΔH ($\Delta H1$, $\Delta H2$, and $\Delta H3$) may depend on a flatness rate R . The flatness rate R may be expressed by an expression (1) illustrated in FIG. 7 or below.

$$\text{Flatness rate } R = W2/W1 \times 100[\%]$$

Expression (1)

[0066] Here, $W1$ may represent a width of a location exposed in the groove **16** on the upper surface of the anode **21**. $W2$ may represent a width of a flat region on the upper surface of the laminate **20A**. The laminate **20A** may be the electron-injection layer **26**, for example. The “flat region” may refer to a region that falls within $\pm 10\%$ from a reference height. The reference height is based on a height of the middle position on the upper surface of the anode **21**. From the standpoint of suppressing a reduction of the emission area, the flatness rate R may be equal to or higher than 50%.

[0067] FIG. 8 illustrates results of measurements of a relationship between the difference ΔH and the flatness rate R . It is seen from FIG. 8 that when the flatness rate R is equal to or higher than 50%, the difference ΔH ($\Delta H1$, $\Delta H2$, and $\Delta H3$) may be equal to or smaller than 500 nm. Note that a lower limit of the difference ΔH ($\Delta H1$, $\Delta H2$, and $\Delta H3$) may depend on constraints in a manufacturing process. For example, a depth of a meniscus, formed as a result of dropping, into the groove **16**, ink at a maximum amount that allows for the dropping without spilling the ink from the groove **16** and drying the ink thereafter in the manufacturing process, may correspond to a lower limit of the difference ΔH ($\Delta H1$, $\Delta H2$, and $\Delta H3$). The depth of the meniscus may be approximately 300 nm, for example. In a process of manufacturing each of the organic electroluminescent elements **12-2**, a meniscus may be formed on an ink liquid surface. A meniscus may also be formed on an upper surface of an ink layer after being dried. For this reason, in each of the organic electroluminescent elements **12-2**, a meniscus may be present to a greater or lesser extent on an upper surface of the hole-injection layer **22**, an upper surface of the hole-transport layer **23**, an upper surface of the organic light-emitting layer **24**, an upper surface of the electron-transport layer **25**, and an upper surface of the electron-injection layer **26**.

[0068] FIG. 6 illustrates one embodiment in which a thickness $D1$ of the film-thickness adjustment layer **28B** is

thicker than a thickness D2 of the film-thickness adjustment layer 28G. The thickness D1 may be equal to t2 and the thickness D2 may be equal to t1. A thickness T1 of the laminate 20A of the subpixel 12B may be thinner than a thickness T2 of the laminate 20A of the subpixel 12G, and the thickness T2 of the laminate 20A of the subpixel 12G is thinner than a thickness T3 of the laminate 20A of the subpixel 12R. The thickness T1 may be equal to t4 and the thickness T2 may be equal to t3. In addition, the optical path length of the resonator 20B may determine the thickness, D1 and D2. Hence, the thickness D1 may not be typically thicker than the thickness D2. There may be some cases in which the thickness D2 is thicker than the thickness D1. In this case, however, the thickness T2 may be thinner than the thickness T1.

[0069] The film-thickness adjustment layer 28 may be disposed on a same surface as a surface where the line bank 13 is disposed. The film-thickness adjustment layer 28 may be so disposed as to be in contact with the upper surface of the substrate 14. Furthermore, the film-thickness adjustment layer 28 may be disposed so that the edges of the film-thickness adjustment layer 28 are embedded in the line banks 13. Therefore, at least a part of the edge of the film-thickness adjustment layer 28 may be located immediately below each of the line banks 13. The film-thickness adjustment layer 28 may be disposed on an entire bottom face of the groove 16, for example. The film-thickness adjustment layer 28 may be in a shape of a strip extending in a direction in which the groove 16 extends, for example. The film-thickness adjustment layer 28 may include an insulating layer of an insulating material such as but not limited to SiO, SiN, or SiON.

[0070] In the following, a shape of an upper part of the line bank 13 is described.

[0071] Suppose that the edges of the film-thickness adjustment layer 28 and the anode 21 are embedded in the line banks 13. In such a case, the upper part of the line bank 13 may have a step that follows the edges of the film-thickness adjustment layer 28 and the anode 21. For example, on an upper part of the line bank 13 provided between the organic electroluminescent element 12b and the organic electroluminescent element 12g, a step 13a may be disposed at a position closer to the organic electroluminescent element 12b. The step 13a may follow the edge of the film-thickness adjustment layer 28B. FIG. 6 illustrates $\Delta H4$ as a height of this step 13a. In addition, on the upper part of the line bank 13 provided between the organic electroluminescent element 12b and the organic electroluminescent element 12g, for example, a step 13b may be disposed at a position closer to the organic electroluminescent element 12g. The step 13b may follow the edge of the film-thickness adjustment layer 28G. FIG. 6 illustrates $\Delta H5$ as a height of this step 13b. In addition, on the upper part of the line bank 13 provided between the organic electroluminescent element 12r and the organic electroluminescent element 12g, for example, a step 13c may be disposed at a position closer to the organic electroluminescent element 12g. The step 13c may follow the edge of the film-thickness adjustment layer 28G. FIG. 6 illustrates $\Delta H6$ as a height of this step 13c.

[0072] The height $\Delta H4$ of the step 13a may be smaller than the thickness D1 of the film-thickness adjustment layer 28B. The height $\Delta H5$ of the step 13b may be smaller than the thickness D2 of the film-thickness adjustment layer 28G. The height $\Delta H6$ of the step 13c may be smaller than the

thickness D2 of the film-thickness adjustment layer 28G. For example, the film-thickness adjustment layer 28B may be of a thickness that does not cause the upper part of the line bank 13 to be raised by the thicknesses D1 and D2 of the film-thickness adjustment layers 28G and 28B upon the formation of the line bank 13 in the manufacturing process. Furthermore, the similar may also hold true for the anode 21. For example, the anode 21 may be of a thickness that does not cause the upper part of the line bank 13 to be raised by the thickness of the anode 21 upon the formation of the line bank 13 in the manufacturing process. In a case where the heights $\Delta H4$, $\Delta H5$, and $\Delta H6$ of the steps 13a, 13b, and 13c disposed on the upper parts of the line banks 13 meet the requirements described above, it is possible to prevent the pinning position on the line bank 13 from shifting upward by the thicknesses D1 and D2 of the film-thickness adjustment layers 28G and 28B. Note that, if the pinning position at the line bank 13 is shifted upward by the thicknesses D1 and D2 of the film-thickness adjustment layers 28G and 28B, the difference OH ($\Delta H1$ and $\Delta H2$) may be almost the same as a case where no film-thickness adjustment layer 28 is provided.

[Manufacturing Method]

[0073] In the following, a method of manufacturing the organic electroluminescent panel 10 is described. FIG. 9A, FIG. 9B, and FIG. 9C illustrate an example of a manufacturing process of the organic electroluminescent panel 10.

[0074] First, film-thickness adjustment layers 28 may be formed on the predetermined subpixels 12 of the plurality of subpixels 12 on the substrate 14 (FIG. 9A). For example, on the substrate 14, the film-thickness adjustment layer 28G may be formed on the subpixel 12G and the film-thickness adjustment layer 28B may be formed on the subpixel 12B. The thickness D2 of the film-thickness adjustment layer 28G and the thickness D1 of the film-thickness adjustment layer 28B may be made different from each other. For example, the thickness D1 of the film-thickness adjustment layer 28B may be made thicker than the thickness D2 of the film-thickness adjustment layer 28G.

[0075] Thereafter, the anode 21 may be formed for each of the subpixels 12 (FIG. 9A). For example, the anode 21 may be formed on the film-thickness adjustment layer 28G as well as on the film-thickness adjustment layer 28B. Thereafter, the plurality of line banks 13 and the plurality of banks 15 may be so formed as to cover edges of the respective film-thickness adjustment layers 28 and the respective anodes 21. This may provide the grooves 16 extending in the row direction. The gap between the two line banks 13 may be set in accordance with a size of definition requested of the organic electroluminescent panel 10. The two line banks 13 may be parallel and adjacent to each other. The gap may be a width W1 of an opening of the groove 16.

[0076] In a process of forming the plurality of line banks 13 and the plurality of banks 15, the respective line banks 13 and the respective banks 15 may be further subjected to surface treatment. Methods of the surface treatment performed for each of the line banks 13 and each of the banks 15 may include, without limitation, wet processing or plasma processing. The wet processing uses a solution containing a predetermined alkaline solution or water, or an organic solvent, for example. The surface treatment to be performed on each of the line banks 13 and each of the line banks 15 with the method described above may, for

example, adjust an angle of inclination of a side face of each of the line banks **13** and each of the banks **15**, or provide liquid repellency for a part of a surface of each of the line banks **13** and each of the banks **15**.

[0077] Thereafter, for example, an ink jet device may be used to discharge ink droplets, following which drying of the discharged ink may be performed to form the hole-injection layer **22** and the hole-transport layer **23** (FIG. 9B). Thereafter, the ink jet device may be used to discharge ink droplets to form an organic material layer **24i** (FIG. 9B). The organic material layer **24i** may be a liquid organic material layer having the organic light-emitting material **24M** as a main component of a solute. For example, the organic material layer **24i** may be first applied into the groove **16**. Thereafter, drying may be performed on the organic material layer **24i** to vaporize a solvent contained in the organic material layer **24i**. This may result in the organic light-emitting layer **24** (FIG. 9C).

[0078] Thereafter, for example, the ink jet device may be used to discharge ink droplets, following which drying of the discharged ink may be performed to form the electron-transport layer **25** and the electron-injection layer **26**. This may be followed by formation of the cathode **27** and the sealing layer **17** on the electron-injection layer **26** in this order. The organic electroluminescent panel **10** having the organic electroluminescent element **12-2** for each of the subpixels **12** may be thus manufactured in this manner.

[Effect]

[0079] In the following, some effects of the organic electroluminescent panel **10** and the organic electroluminescent unit **1** provided with the same are described.

[0080] There is known a method of manufacturing an organic electroluminescent panel by forming an organic electroluminescent element for each pixel with use of an ink jet device. A recent increase in definition has brought a reduction in pixel size and a reduction of a liquid amount to be retained per unit area. From the standpoint of solubility or a printable physical property such as viscosity, however, it is difficult to excessively increase an ink concentration. To address this, a method may be contemplated in which an amount of retained liquid is increased as much as possible by, for example, making side faces of partition walls that define the pixels lyophilic.

[0081] If the side faces of the banks are made lyophilic, however, a meniscus is formed on an ink surface in a process of drying ink. The meniscus is also formed on an upper surface of an ink layer after being dried. This makes a bank vicinity extremely thick in the ink layer, causing a phenomenon that a center part of a pixel emits light strongly. As a result, a part that is usable as a light-emitting part is reduced. Hence, it is desirable to provide an organic electroluminescent element, an organic electroluminescent panel, and a luminescent unit that make it possible to suppress a reduction in the part that is usable as the light-emitting part.

[0082] In contrast, in one embodiment, the film-thickness adjustment layer **28** is provided at the position that is outside of the resonator **20B** and closer to the reflecting surface **21A**. This film-thickness adjustment layer **28** has a thickness that is adjusted to allow the difference ΔH ($\Delta H1$ and $\Delta H2$) between the height H ($H1$ and $H2$) of the pinning position and the height T ($T1$ and $T2$) of the middle position of the upper surface of the laminate **20A** to fall within a predetermined range. The pinning position is where the upper

surface of the laminate **20A** and the line banks **13** are in contact with each other. This makes it possible to make a depth of a meniscus to be formed on the laminate **20A** shallower than a case in which no film-thickness adjustment layer **28** is provided. Thus, the percentage of the part that is unusable as the light-emitting part of the organic light-emitting layer **24** is reduced. Consequently, it is possible to suppress the reduction of the usable part as the light-emitting part of the organic light-emitting layer **24**.

[0083] In addition, in one embodiment, the difference ΔH ($\Delta H1$, $\Delta H2$, and $\Delta H3$) may be equal to or smaller than 500 nm. In this case, the flatness rate R of the laminate **20A** may be equal to or larger than 50%. This reduces the percentage of the part that is unusable as the light-emitting part of the organic light-emitting layer **24**. Consequently, it is possible to suppress the reduction of the usable part as the light-emitting part of the organic light-emitting layer **24**.

[0084] In addition, in one embodiment, at least a part of the edge of the film-thickness adjustment layer **28** may be located immediately below each of the line banks **13**. The steps **13a**, **13b**, and **13c** may be disposed on upper parts of the respective line banks **13** and follow the edges of the film-thickness adjustment layer **28**. The steps **13a**, **13b**, and **13c** may have a thickness smaller than that of the film-thickness adjustment layer **28**. This makes it possible to make the depth of the meniscus to be formed on the laminate **20A** shallower than the case in which no film-thickness adjustment layer **28** is provided. Thus, the percentage of the part that is unusable as the light-emitting part of the organic light-emitting layer **24** is reduced. Consequently, it is possible to suppress the reduction of the usable part as the light-emitting part of the organic light-emitting layer **24**.

[0085] In addition, in one embodiment, the organic electroluminescent elements **12r**, **12g**, and **12b** may have the anode **21** having the reflecting surface **21A**, and the film-thickness adjustment layer **28** may be an insulating layer in contact with the anode **21**. This allows such an adjustment as to keep the differences ΔH ($\Delta H1$ and $\Delta H2$) within a predetermined range simply by adjusting the thickness of the film-thickness adjustment layer **28**. Therefore, it is possible to suppress the reduction of the part that is usable as the light-emitting part of the organic light-emitting layer **24** in a simple manner.

MODIFICATION EXAMPLES

[0086] Modification examples of the organic electroluminescent unit **1** according to some embodiments described above are described below.

Modification Example A

[0087] In some embodiments described above, the film-thickness adjustment layer **28** may be provided only for two of the organic electroluminescent elements **12-2** in one pixel **11**. However, the film-thickness adjustment layer **28** may be provided for only one of the organic electroluminescent elements **12-2** in one pixel **11**. Alternatively, the film-thickness adjustment layer **28** may be provided for all of the organic electroluminescent elements **12-2** in one pixel **11**. As illustrated in FIG. 10, for example, the film-thickness adjustment layer **28** may be provided only for the organic electroluminescent element **12b**. In addition, as illustrated in FIG. 11, for example, the film-thickness adjustment layer **28** may be provided for the organic electroluminescent ele-

ments 12r, 12g, and 12b. FIG. 10 and FIG. 11 illustrate one modification example of a cross-sectional configuration of the organic electroluminescent panel 10 of FIG. 4.

Modification Example B

[0088] In addition, in some embodiments and the modification example thereof as described above, the edge of the anode 21 may be located more inside than the edge of the film-thickness adjustment layer 28. However, as illustrated in FIG. 12, for example, in some embodiments and the modification example thereof as described above, the anode 21 may be so provided that the anode 21 is in contact with a surface of the film-thickness adjustment layer 28 and the edge of the anode 21 is directly above the edge of the film-thickness adjustment layer 28.

[0089] In this case, at least a part of the respective edges of the film-thickness adjustment layer 28 and the anode 21 may be located immediately below each of the line banks 13. Furthermore, on an upper part of the line bank 13, the step 13a may be disposed at a position closer to the organic electroluminescent element 12b. The step 13a may follow the respective edges of the film-thickness adjustment layer 28B and the anode 21. This step 13a may have a height $\Delta H4$ corresponding to a sum of thicknesses of the film-thickness adjustment layer 28B and the anode 21. In addition, on the upper part of the line bank 13 provided between the organic electroluminescent element 12b and the organic electroluminescent element 12g, the step 13b may be disposed at a position closer to the organic electroluminescent element 12g. The step 13b may follow the respective edges of the film-thickness adjustment layer 28G and the anode 21. This step 13b may have a height $\Delta H5$ corresponding to the sum of the thicknesses of the film-thickness adjustment layer 28G and the anode 21. In addition, on the upper part of the line bank 13 provided between the organic electroluminescent element 12r and the organic electroluminescent element 12g, the step 13c may be disposed at a position closer to the organic electroluminescent element 12g. The step 13c may follow the respective edges of the film-thickness adjustment layer 28G and the anode 21. This step 13c may have a height $\Delta H6$ corresponding to the sum of thicknesses of the film-thickness adjustment layer 28G and the anode 21.

[0090] In this modification example, the height $\Delta H4$ of the step 13a may be smaller than the sum of the thickness D1 of the film-thickness adjustment layer 28B and the thickness of the anode 21. The height $\Delta H5$ of the step 13b may be smaller than the sum of the thickness D2 of the film-thickness adjustment layer 28G and the thickness of the anode 21. The height $\Delta H6$ of the step 13c may be smaller than the sum of the thickness D2 of the film-thickness adjustment layer 28G and the thickness of the anode 21. For example, the film-thickness adjustment layer 28B may be of thickness that does not cause the upper part of the line bank 13 to be raised by the sum of the thicknesses D1 and D2 of the film-thickness adjustment layers 28G and 28B and the thickness of the anode 21 upon the formation of the line bank in the manufacturing process. This prevents the pinning position on the line bank 13 from shifting upward by the sum of the thicknesses D1 and D2 of the film-thickness adjustment layers 28G and 28B and the thickness of the anode 21. Consequently, this allows the depth of the meniscus to be formed on the laminate 20A to be shallower than the case where no film-thickness adjustment layer 28 is provided. This reduces the percentage of the part that is unusable as the

light-emitting part of the organic light-emitting layer 24. Therefore, it is possible to suppress the reduction of the part usable as the light-emitting part of the organic light-emitting layer 24.

Modification Example C

[0091] In some embodiments and the modification examples thereof as described above, the anode 21 may be provided in contact with a part of the surface of the film-thickness adjustment layer 28. However, as illustrated in FIG. 13, for example, in some embodiments and the modification examples thereof as described above, the anode 21 may be so provided as to cover an entire surface of the film-thickness adjustment layer 28.

[0092] In this case, on the upper part of the line bank 13 provided between the organic electroluminescent element 12b and the organic electroluminescent element 12g, the step 13a may be disposed at a position closer to the organic electroluminescent element 12b. The step 13a may follow the edge of the film-thickness adjustment layer 28B. FIG. 13 illustrates $\Delta H4$ as a height of this step 13a. In addition, on the upper part of the line bank 13 provided between the organic electroluminescent element 12b and the organic electroluminescent element 12g, for example, the step 13b may be disposed at a position closer to the organic electroluminescent element 12g. The step 13b may follow the edge of the film-thickness adjustment layer 28G. FIG. 13 illustrates $\Delta H5$ as a height of this step 13b. In addition, on the upper part of the line bank 13 provided between the organic electroluminescent element 12r and the organic electroluminescent element 12g, for example, the step 13c may be disposed at a position closer to the organic electroluminescent element 12g. The step 13c may follow the edge of the film-thickness adjustment layer 28G. FIG. 13 illustrates $\Delta H6$ as a height of this step 13c.

[0093] In this modification example, the height $\Delta H4$ of the step 13a may be smaller than the thickness D1 of the film-thickness adjustment layer 28B. Furthermore, in the anode 21, a height of a step disposed in the vicinity of the edge of the film-thickness adjustment layer 28B may be substantially equal to the thickness D1 of the film-thickness adjustment layer 28B. The height $\Delta H5$ of the step 13b may be smaller than the thickness D2 of the film-thickness adjustment layer 28G. The height $\Delta H6$ of the step 13c may be smaller than the thickness D2 of the film-thickness adjustment layer 28G. Furthermore, in the anode 21, a height of a step disposed in the vicinity of the edge of the film-thickness adjustment layer 28G may be substantially equal to the thickness D2 of the film-thickness adjustment layer 28G. In this modification example, the film-thickness adjustment layer 28B may be of thickness that does not cause the upper part of the line bank 13 to be raised by the thicknesses D1 and D2 of the film-thickness adjustment layers 28G and 28B upon the formation of the line bank 13 in the manufacturing process. Furthermore, the similar may also hold true for the anode 21. For example, the anode 21 may be of a thickness that does not cause the upper part of the line bank 13 to be raised by the thickness of the anode 21 upon the formation of the line bank 13 in the manufacturing process. In a case where the heights $\Delta H4$, $\Delta H5$, and $\Delta H6$ of the steps 13a, 13b, and 13c disposed on the upper parts of the line banks 13 meet the requirements described above, it is possible to prevent the pinning position on the line bank 13 from shifting upward by the thicknesses D1 and

D2 of the film-thickness adjustment layers 28G and 28B. Consequently, this allows the depth of the meniscus to be formed on the laminate 20A to be shallower than the case where no film-thickness adjustment layer 28 is provided. This reduces the percentage of the part that is unusable as the light-emitting part of the organic light-emitting layer 24. Therefore, it is possible to suppress the reduction of the part usable as the light-emitting part of the organic light-emitting layer 24.

Modification Example D

[0094] In addition, in some embodiments and the modification examples thereof as described above, the film-thickness adjustment layer 28 may be provided to make an adjustment so as to keep the differences ΔH ($\Delta H1$ and $\Delta H2$) within a predetermined range. In some embodiments and the modification examples thereof as described above, however, the film-thickness adjustment layer 28 may be omitted and the anode 21 may also serve as the film-thickness adjustment layer 28. As illustrated in FIG. 14, FIG. 15, and FIG. 16, for example, an anode 21B may serve as the film-thickness adjustment layer 28B in the organic electroluminescent element 12b, and the anode 21G may serve as the film-thickness adjustment layer 28G in the organic electroluminescent element 12g. Furthermore, the anode 21G may also serve as the film-thickness adjustment layer 28G in the organic electroluminescent element 12r.

[0095] In this modification example, the anode 21 may be disposed on the substrate 14. The edges of the anode 21 may be embedded in the line banks 13. In such an example, the line bank 13 may have a step on the upper part. The step may follow the edge of the anode 21. For example, on the upper part of the line bank 13 provided between the organic electroluminescent element 12b and the organic electroluminescent element 12g, a step 13d may be disposed at a position closer to the organic electroluminescent element 12b. The step 13d may follow the edge of the anode 21B. FIG. 16 illustrates $\Delta H7$ as a height of this step 13d. In addition, on the upper part of the line bank 13 provided between the organic electroluminescent element 12b and the organic electroluminescent element 12g, for example, a step 13e may be disposed at a position closer to the organic electroluminescent element 12g. The step 13e may follow the edge of the anode 21G. FIG. 16 illustrates $\Delta H8$ as a height of this step 13e. In addition, on the upper part of the line bank 13 provided between the organic electroluminescent element 12r and the organic electroluminescent element 12g, for example, a step 13f may be disposed at a position closer to the organic electroluminescent element 12g. The step 13f may follow the edge of the anode 21G. FIG. 16 illustrates $\Delta H9$ as a height of this step 13f.

[0096] The height $\Delta H7$ of the step 13d may be smaller than a thickness L1 of the anode 21B. The height $\Delta H8$ of the step 13e may be smaller than a thickness L2 of the anode 21G. The height $\Delta H9$ of the step 13f may be smaller than the thickness L2 of the anode 21G. For example, the anodes 21B and 21G may have a thickness that does not cause the upper part of the line bank 13 to be raised by the thicknesses L1 and L2 of the anodes 21B and 21G upon the formation of the line bank 13 in the manufacturing process. In a case where the heights $\Delta H7$, $\Delta H8$, and $\Delta H9$ of the steps 13d, 13e, and 13f disposed on the upper parts of the line banks 13 meet the requirements described above, it is possible to prevent the pinning position on the line bank 13 from shifting upward by

the thicknesses L1 and L2 of the film-thickness adjustment layers 28G and 28B. Note that, if the pinning position at the line bank 13 is shifted upward by the thicknesses L1 and L2 of the anodes 21B and 21G, the difference ΔH ($\Delta H1$ and $\Delta H2$) may be almost the same as a case where no film-thickness adjustment layer 28 is provided.

[0097] Thus, in this modification example, it is possible to make an adjustment so as to keep the difference ΔH ($\Delta H1$, $\Delta H2$, and $\Delta H3$) within the predetermined range simply by adjusting the thickness of the anode 21. Therefore, it is possible to suppress the reduction of the part usable as the light-emitting part of the organic light-emitting layer 24 in a simple manner.

Modification Example E

[0098] In some embodiments and the modification examples thereof as described above, the line bank 13 may have one pinning position disposed on corresponding one of both side faces. However, the pinning position to be disposed on the corresponding one of both side faces of the line bank 13 may be more than one. As illustrated in FIG. 17 and FIG. 18, for example, the pinning positions to be disposed on one of the side faces of the line bank 13 may be two locations. FIG. 17 illustrates one modification example of a cross-sectional configuration of the organic electroluminescent panel 10 of FIG. 6. FIG. 18 illustrates one modification example of a cross-sectional configuration of the organic electroluminescent panel 10 of FIG. 16.

[0099] In FIG. 17 and FIG. 18, the line bank 13 may have a configuration in which a line bank 13B is stacked on a line bank 13A. The line bank 13A may correspond to a specific example of a "first partition wall" in one embodiment of the disclosure. The line bank 13B may correspond to a specific example of a "second partition wall" in one embodiment of the disclosure. One pinning position may be provided for corresponding one of both side faces of the line bank 13A, and one pinning position may be provided for corresponding one of both side faces of the line bank 13B. The line bank 13A may have a pinning position P1 where an upper surface of the hole-injection layer 22 and an upper surface of the hole-transport layer 23 and the line bank 13A are in contact with each other. The hole-injection layer 22 and the hole-transport layer 23 may be closer to the reflecting surfaces 21A and 29A than the organic light-emitting layer 24. In contrast, the line bank 13B may have a pinning position P2 where the upper surface of the organic light-emitting layer 24, an upper surface of the electron-transport layer 25 and an upper surface of the electron-injection layer 26, and the line bank 13B are in contact with each other. The electron-transport layer 25 and the electron-injection layer 26 may be closer to the reflecting surface 27A than the organic light-emitting layer 24. The pinning position P1 may correspond to a boundary position between a lyophilic region and a liquid-repellent region on the side face of the line bank 13A, for example. In addition, the pinning position P2 may correspond to a boundary position between a lyophilic region and a liquid-repellent region on the side face of the line bank 13B, for example. In this modification example, the hole-injection layer 22 and the hole-transport layer 23 may correspond to a specific example of a "first organic material layer" in one embodiment of the disclosure. In this modification example, the electron-transport layer 25 and

the electron-injection layer **26** may correspond to a specific example of a “second organic material layer” in one embodiment of the disclosure.

[0100] As such, the plurality of pinning positions are disposed for the corresponding one of both side faces of the line bank **13**. Thus, the depth of the meniscus of each layer contained in the laminate **20A** is made shallower than a case in which one pinning position is disposed for the corresponding one of both side faces of the line bank **13A**. This reduces the percentage of the part that is unusable as the light-emitting part of the organic light-emitting layer **24**. Consequently, it is possible to suppress the reduction of the part that is usable as the light-emitting part of the organic light-emitting layer **24**.

[0101] Although the disclosure has been described by referring to some embodiments, it is not limited thereto but various modifications are possible. For example, in some embodiments described above, the plurality of line banks **13** and the plurality of banks **15** are provided on the substrate **14**. Alternatively, one pixel bank may be provided for each of the subpixels **12**.

[0102] It should be noted that the effects described herein are merely exemplary. The effects of the disclosure are not limited to those described herein. The disclosure may have other effects than those described herein.

[0103] It is possible to achieve the following configurations from the disclosure.

[0104] (1) An organic electroluminescent element including:

[0105] an organic electroluminescent part; and

[0106] a pair of partition walls provided on both sides of the organic electroluminescent part,

[0107] the organic electroluminescent part including

[0108] an organic material layer including a light-emitting layer that emits electroluminescence light,

[0109] a resonator that is in contact with the organic material layer, and includes an anode-side reflecting surface and a cathode-side reflecting surface that face each other with the organic material layer provided therebetween, and

[0110] a film-thickness adjustment layer provided at a position that is outside of the resonator and closer to the anode-side reflecting surface, and having a thickness that is adjusted to allow a difference between a height of a pinning position and a height of a middle position of an upper surface of the organic material layer to fall within a predetermined range, the pinning position being a position at which the upper surface of the organic material layer and each of the partition walls are in contact with each other.

[0111] (2) The organic electroluminescent element according to (1), in which the difference is equal to or smaller than 500 nm.

[0112] (3) The organic electroluminescent element according to (1) or (2), in which

[0113] at least a part of an edge of the film-thickness adjustment layer is located below each of the partition walls,

[0114] the partition walls each have a step that follows the edge of the film-thickness adjustment layer, and

[0115] the step is smaller than the thickness of the film-thickness adjustment layer.

[0116] (4) The organic electroluminescent element according to (1) or (2), in which

[0117] the organic electroluminescent part includes an anode electrode having the anode-side reflecting surface,

[0118] the anode electrode is in contact with a surface of the film-thickness adjustment layer and provided to allow an edge of the anode electrode to be located above an edge of the film-thickness adjustment layer,

[0119] at least a part of the edge of the film-thickness adjustment layer and at least a part of the edge of the anode electrode are located below each of the partition walls,

[0120] the partition walls each have a step that follows the edge of the film-thickness adjustment layer and the edge of the anode electrode, and

[0121] the step is smaller than a sum of the thickness of the film-thickness adjustment layer and a thickness of the anode electrode.

[0122] (5) The organic electroluminescent element according to any one of (1) to (3), in which

[0123] the organic electroluminescent part includes an anode electrode having the anode-side reflecting surface, and

[0124] the anode electrode serves as the film-thickness adjustment layer.

[0125] (6) The organic electroluminescent element according to any one of (1), (2), and (4), in which

[0126] the organic electroluminescent part includes an anode electrode having the anode-side reflecting surface, and

[0127] the film-thickness adjustment layer includes an insulating layer that is in contact with the anode electrode.

[0128] (7) The organic electroluminescent element according to any one of (1) to (6), in which

[0129] the partition walls each include a first partition wall and a second partition wall stacked on the first partition wall,

[0130] the organic material layer includes, in addition to the light-emitting layer, one or more first organic material layers provided closer to the anode-side reflecting surface and one or more second organic material layers closer provided to the cathode-side reflecting surface,

[0131] the first partition wall has a pinning position at which an upper surface of the first organic material layer and the first partition wall are in contact with each other, and

[0132] the second partition wall has a pinning position at which an upper surface of the second organic material layer and the second partition wall are in contact with each other.

[0133] (8) An organic electroluminescent panel including

[0134] a plurality of pixels each including a plurality of subpixels,

[0135] in each of the pixels, at least one of the subpixels including

[0136] an organic electroluminescent part, and

[0137] a pair of partition walls provided on both sides of the organic electroluminescent part,

[0138] the organic electroluminescent part including

[0139] an organic material layer including a light-emitting layer that emits electroluminescence light,

- [0140] a resonator that is in contact with the organic material layer, and includes an anode-side reflecting surface and a cathode-side reflecting surface that face each other with the organic material layer provided therebetween, and
- [0141] a film-thickness adjustment layer provided at a position that is outside of the resonator and closer to the anode-side reflecting surface, and having a thickness that is adjusted to allow a difference between a height of a pinning position and a height of a middle position of an upper surface of the organic material layer to fall within a predetermined range, the pinning position being a position at which the upper surface of the organic material layer and each of the partition walls are in contact with each other.
- [0142] (9) The organic electroluminescent panel according to (8),
- [0143] in which, in each of the pixels, at least two of the subpixels each include the organic electroluminescent part and the pair of partition walls, and
- [0144] in which, in each of the pixels, the thickness of the film-thickness adjustment layer of a first subpixel in the subpixels and the thickness of the film-thickness adjustment layer of a second subpixel, different from the first subpixel, in the subpixels satisfy the following relational expression:
- $$t1 < t2$$
- [0145] where $t1$ is the thickness of the film-thickness adjustment layer of the first subpixel, and $t2$ is the thickness of the film-thickness adjustment layer of the second subpixel.
- [0146] (10) The organic electroluminescent panel according to (9), in which, in each of the pixels, a thickness of the organic material layer of the first subpixel and a thickness of the organic material layer of the second subpixel satisfy the following relational expression:
- $$t3 > t4$$
- [0147] where $t3$ is the thickness of the organic material layer of the first subpixel, and $t4$ is the thickness of the organic material layer of the second subpixel.
- [0148] (11) The organic electroluminescent panel according to any one of (8) to (10), in which, in each of the pixels, the difference of the first subpixel and the difference of the second subpixel are each equal or smaller than 500 nm.
- [0149] (12) A luminescent unit including:
- [0150] an organic electroluminescent panel including a plurality of pixels; and
- [0151] a driver that drives the plurality of pixels,
- [0152] the plurality of pixels each including a plurality of subpixels,
- [0153] in each of the pixels, at least one of the subpixels including
- [0154] an organic electroluminescent part, and
- [0155] a pair of partition walls provided on both sides of the organic electroluminescent part,
- [0156] the organic electroluminescent part including
- [0157] an organic material layer including a light-emitting layer that emits electroluminescence light,
- [0158] a resonator that is in contact with the organic material layer, and includes an anode-side reflecting

surface and a cathode-side reflecting surface that face each other with the organic material layer provided therebetween, and

- [0159] a film-thickness adjustment layer provided at a position that is outside of the resonator and closer to the anode-side reflecting surface, and having a thickness that is adjusted to allow a difference between a height of a pinning position and a height of a middle position of an upper surface of the organic material layer to fall within a predetermined range, the pinning position being a position at which the upper surface of the organic material layer and each of the partition walls are in contact with each other.
- [0160] In the organic electroluminescent element, the organic electroluminescent panel, and the luminescent unit according to respective example embodiments of the disclosure, the film-thickness adjustment layer is provided at the position that is outside of the resonator and closer to the anode reflecting surface. The film-thickness adjustment layer has the thickness that is adjusted to allow the difference between the height of the pinning position and the height of the middle position of the upper surface of the organic material layer to fall within a predetermined range. The pinning position is a position at which the upper surface of the organic material layer and each of the partition walls are in contact with each other. This makes it possible to make a depth of a meniscus to be formed on the organic material layer shallower than a case in which no film-thickness adjustment layer is provided. Thus, a percentage of a part that is unusable as a light-emitting part of a light-emitting layer is reduced.
- [0161] The organic electroluminescent element, the organic electroluminescent panel, and the luminescent unit according to the respective example embodiments of the disclosure make it possible to make the depth of the meniscus to be formed on the organic material layer shallower than an existing organic electroluminescent panel. Since this reduces the percentage of the part that is unusable as the light-emitting part in the light-emitting layer, it is possible to suppress the reduction of the part that is usable as the light-emitting part of the light-emitting layer.
- [0162] It should be noted that the effect of the disclosure is not limited to what is described here but may include any effect described herein.
- [0163] It should be understood by those skilled in the art that various modifications, combinations, sub-combinations and alterations may occur depending on design requirements and other factors insofar as they are within the scope of the appended claims or the equivalents thereof.
- What is claimed is:
1. An organic electroluminescent element comprising:
 - an organic electroluminescent part; and
 - a pair of partition walls provided on both sides of the organic electroluminescent part,
 the organic electroluminescent part including
 - an organic material layer including a light-emitting layer that emits electroluminescence light,
 - a resonator that is in contact with the organic material layer, and includes an anode-side reflecting surface and a cathode-side reflecting surface that face each other with the organic material layer provided therebetween, and

- a film-thickness adjustment layer provided at a position that is outside of the resonator and closer to the anode-side reflecting surface, and having a thickness that is adjusted to allow a difference between a height of a pinning position and a height of a middle position of an upper surface of the organic material layer to fall within a predetermined range, the pinning position being a position at which the upper surface of the organic material layer and each of the partition walls are in contact with each other.
2. The organic electroluminescent element according to claim 1, wherein the difference is equal to or smaller than 500 nm.
 3. The organic electroluminescent element according to claim 1, wherein
 - at least a part of an edge of the film-thickness adjustment layer is located below each of the partition walls,
 - the partition walls each have a step that follows the edge of the film-thickness adjustment layer, and
 - the step is smaller than the thickness of the film-thickness adjustment layer.
 4. The organic electroluminescent element according to claim 1, wherein
 - the organic electroluminescent part includes an anode electrode having the anode-side reflecting surface,
 - the anode electrode is in contact with a surface of the film-thickness adjustment layer and provided to allow an edge of the anode electrode to be located above an edge of the film-thickness adjustment layer,
 - at least a part of the edge of the film-thickness adjustment layer and at least a part of the edge of the anode electrode are located below each of the partition walls,
 - the partition walls each have a step that follows the edge of the film-thickness adjustment layer and the edge of the anode electrode, and
 - the step is smaller than a sum of the thickness of the film-thickness adjustment layer and a thickness of the anode electrode.
 5. The organic electroluminescent element according to claim 1, wherein
 - the organic electroluminescent part includes an anode electrode having the anode-side reflecting surface, and
 - the anode electrode serves as the film-thickness adjustment layer.
 6. The organic electroluminescent element according to claim 1, wherein
 - the organic electroluminescent part includes an anode electrode having the anode-side reflecting surface, and
 - the film-thickness adjustment layer comprises an insulating layer that is in contact with the anode electrode.
 7. The organic electroluminescent element according to claim 1, wherein
 - the partition walls each include a first partition wall and a second partition wall stacked on the first partition wall,
 - the organic material layer includes, in addition to the light-emitting layer, one or more first organic material layers provided closer to the anode-side reflecting surface and one or more second organic material layers closer provided to the cathode-side reflecting surface,
 - the first partition wall has a pinning position at which an upper surface of the first organic material layer and the first partition wall are in contact with each other, and
 - the second partition wall has a pinning position at which an upper surface of the second organic material layer and the second partition wall are in contact with each other.
 8. An organic electroluminescent panel comprising
 - a plurality of pixels each including a plurality of subpixels,
 - in each of the pixels, at least one of the subpixels including
 - an organic electroluminescent part, and
 - a pair of partition walls provided on both sides of the organic electroluminescent part,
 - the organic electroluminescent part including
 - an organic material layer including a light-emitting layer that emits electroluminescence light,
 - a resonator that is in contact with the organic material layer, and includes an anode-side reflecting surface and a cathode-side reflecting surface that face each other with the organic material layer provided therebetween, and
 - a film-thickness adjustment layer provided at a position that is outside of the resonator and closer to the anode-side reflecting surface, and having a thickness that is adjusted to allow a difference between a height of a pinning position and a height of a middle position of an upper surface of the organic material layer to fall within a predetermined range, the pinning position being a position at which the upper surface of the organic material layer and each of the partition walls are in contact with each other.
 9. The organic electroluminescent panel according to claim 8,
 - wherein, in each of the pixels, at least two of the subpixels each include the organic electroluminescent part and the pair of partition walls, and
 - wherein, in each of the pixels, the thickness of the film-thickness adjustment layer of a first subpixel in the subpixels and the thickness of the film-thickness adjustment layer of a second subpixel, different from the first subpixel, in the subpixels satisfy the following relational expression:

$$t1 < t2$$
 where $t1$ is the thickness of the film-thickness adjustment layer of the first subpixel, and $t2$ is the thickness of the film-thickness adjustment layer of the second subpixel.
 10. The organic electroluminescent panel according to claim 9, wherein, in each of the pixels, a thickness of the organic material layer of the first subpixel and a thickness of the organic material layer of the second subpixel satisfy the following relational expression:

$$t3 > t4$$
 where $t3$ is the thickness of the organic material layer of the first subpixel, and $t4$ is the thickness of the organic material layer of the second subpixel.
 11. The organic electroluminescent panel according to claim 8, wherein, in each of the pixels, the difference of the first subpixel and the difference of the second subpixel are each equal or smaller than 500 nm.
 12. A luminescent unit comprising:
 - an organic electroluminescent panel including a plurality of pixels; and
 - a driver that drives the plurality of pixels,

the plurality of pixels each including a plurality of sub-pixels,
in each of the pixels, at least one of the subpixels including
an organic electroluminescent part, and
a pair of partition walls provided on both sides of the organic electroluminescent part,
the organic electroluminescent part including
an organic material layer including a light-emitting layer that emits electroluminescence light,
a resonator that is in contact with the organic material layer, and includes an anode-side reflecting surface and a cathode-side reflecting surface that face each other with the organic material layer provided therebetween, and
a film-thickness adjustment layer provided at a position that is outside of the resonator and closer to the anode-side reflecting surface, and having a thickness that is adjusted to allow a difference between a height of a pinning position and a height of a middle position of an upper surface of the organic material layer to fall within a predetermined range, the pinning position being a position at which the upper surface of the organic material layer and each of the partition walls are in contact with each other.

* * * * *

专利名称(译)	有机电致发光元件，有机电致发光面板和发光单元		
公开(公告)号	US20180254303A1	公开(公告)日	2018-09-06
申请号	US15/885089	申请日	2018-01-31
申请(专利权)人(译)	JOLED INC.		
当前申请(专利权)人(译)	JOLED INC.		
[标]发明人	MISHIMA KOSUKE		
发明人	MISHIMA, KOSUKE		
IPC分类号	H01L27/32 H01L51/52 G09G3/3208		
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摘要(译)

有机电致发光元件包括有机电致发光部分和一对分隔壁。有机电致发光部分包括有机材料层，谐振器和膜厚度调节层。膜厚度调节层的厚度被调节为允许钉扎位置的高度与有机材料层的上表面的中间位置的高度之间的差落入预定范围内。钉扎位置是有机材料层的上表面和每个分隔壁彼此接触的位置。

